

Optical and near-infrared recombination lines of oxygen ions from Cassiopeia A knots[★]

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Received 14 February 2008 / Accepted 21 March 2008

ABSTRACT

Context. Fast-moving knots (FMK) in the Galactic supernova remnant Cassiopeia A consist mainly of metals and allow us to study element production in supernovae and to investigate shock physics in great detail.

Aims. We discuss and suggest observations of a previously unexplored class of spectral lines, the metal recombination lines in optical and near-infrared bands, emitted by the cold ionized and cooling plasma in fast-moving knots.

Methods. By tracing ion radiative and dielectronic recombination, collisional *l*-redistribution and radiative cascade processes, we compute resulting oxygen, silicon and sulphur recombination line emissivities. This allows us to determine the oxygen recombination line fluxes, based on a fast-moving knot model that predicts the existence of highly-ionized ions from moderate to very low plasma temperatures.

Results. The calculations predict oxygen ion recombination line fluxes detectable with modern optical telescopes in the wavelength range from 0.5 to 3 μm . Recombination line flux ratios to collisionally-excited lines will allow us to probe in detail the process of rapid cloud cooling after the passage of a shock front, to test high abundances of O^{4+} , O^{5+} and O^{6+} ions at low temperatures and measure them, to test existing theoretical models of FMK and to build more precise ones.

Key words. atomic processes – supernovae: individual: Cassiopeia A – infrared: ISM

1. Introduction

The brightest source on the radio sky, the supernova remnant Cassiopeia A, is so close and so young that modern instruments are able to observe exceptionally fine details in its rich structure in different spectral bands. One of the most interesting phenomena are dense ejecta blobs of the supernova explosion, observed as numerous bright optical “fast-moving knots” (FMKs). These knots radiate mostly in the [O III] doublet near 5000 Å and in other forbidden lines of oxygen, sulphur, silicon and argon.

Early observations using the 200-inch telescope on Mount Palomar (Baade & Minkowski 1954; Minkowski & Aller 1954; Minkowski 1957) demonstrated that the emitting knot plasma has temperatures of about 2×10^4 K and electron densities of about 10^4 cm^{-3} . Very unusual spectra of the fast-moving knots lead Shklovskii (1968) to the suggestion, later confirmed by detailed measurements and analysis (Peimbert & van den Bergh 1971; Chevalier & Kirshner 1978, 1979), that they have extremely high abundances of some of heavy elements. Some of the knots consist of up to 90% of oxygen, others contain predominantly heavier elements, such as silicon, sulphur, argon and calcium (Chevalier & Kirshner 1979; Hurford & Fesen 1996).

It was also discovered that a typical lifetime of a FMK is of the order of 10–30 years (Kamper & van den Bergh 1976). Existing knots disappear, but other bright knots appear on the maps of Cassiopeia A (hereafter Cas A).

Detailed Chandra observations (Hughes et al. 2000; Hwang et al. 2004) revealed the presence of similar knots in X-rays, being very bright in spectral lines of hydrogen- and helium-like ions of silicon and sulphur and showing traces of heavily absorbed oxygen X-ray lines.

Similar bright optical knots are observed in other oxygen-rich supernova remnants (e.g., Puppis A, N132D, etc., Sutherland & Dopita 1995a), but the case of Cas A is the most promising for further investigations.

The FMK optical spectra were first treated as shock wave emission by Chevalier & Kirshner (1978, 1979). Subsequently it was understood that the shock models used, that assumed solar abundances, are inappropriate for the case of the FMK plasma, as its high metal abundances result in a different shock structure.

There have been several theoretical models published describing the shock emission in pure oxygen plasmas (Itoh 1981a,b; Borkowski & Shull 1990) and oxygen-dominated plasmas (Sutherland & Dopita 1995b, hereafter SD95). In these models, the reverse shock of the supernova remnant encounters a dense knot and decelerates on entering its dense medium (Zel’dovich & Raizer 1967; McKee & Cowie 1975) to velocities of several hundred km s^{-1} . Shortly after the shock wave enters the cloud, the material ahead of the shock front is ionized by the radiation from the heated gas behind the shock front. All the theoretical models assume shock wave propagation with a constant velocity through a constant density cloud.

The optical emission is formed in two relatively thin layers: one immediately following the shock front, where plasma rapidly cools from X-ray emitting temperatures of about 5×10^6 K to below 10^3 K and another at the photoionization front

[★] Tables 5 to 23 are only available in electronic form at the CDS via anonymous ftp to cdsarc.u-strasbg.fr (130.79.128.5) or via <http://cdsweb.u-strasbg.fr/cgi-bin/qcat?J/A+A/484/755>

before the shock wave. The relatively cold layers with temperatures below 10^5 K contribute most strongly to the line emission, as approximate pressure equilibrium results in much higher densities and emission measures of these regions.

An important detail is that *the recombination time is much longer than the plasma cooling time*. Therefore recombining and cooling plasma simultaneously contains ions in very different ionization stages at all temperatures down to several hundred Kelvin – the plasma is in a non-equilibrium ionization state. It is very important to find a way to confirm experimentally this prediction of the computational models.

Predictions of various theoretical models differ in many ways. For example, as we show in an accompanying article (Docenko & Sunyaev, to be submitted), the model predictions of the fine-structure far-infrared line intensities differ by several orders of magnitude. We also show there that the models of SD95 and of Borkowski & Shull (1990) are the best available ones in reproducing the far-infrared line emission of the fast-moving knots, although each is only precise up to a factor of a few.

Nevertheless, these two theoretical models still have many differences. For example, in the Borkowski & Shull (1990) models the O^{4+} and higher-ionized species are essentially absent, whereas in the SD95 model O^{6+} is the dominant ion after the shock at temperatures above about 5000 K. Unfortunately, O^{4+} , O^{5+} and O^{6+} ions have no collisionally-excited lines in visible and infrared ranges, and their ultraviolet and soft X-ray lines are almost or completely undetectable due to high interstellar absorption on the way from Cas A.

From the large differences between the theoretical model predictions it is clear that they lack observational constraints and more diagnostic information in the form of various line ratios is needed to pin down the true structure of fast-moving knots. Some of such information can be obtained from the far-infrared lines.

In this paper we argue that still more information may be obtained from metal recombination lines (RL) in optical and near-infrared spectral ranges. These lines arise in the transitions between highly-excited levels (principal quantum number $n \approx 5-10$) populated by the processes of dielectronic and radiative recombination. The RLs are emitted by *all* ionic species, including, for example, O^{4+} and O^{5+} that have no other lines detectable from Cas A.

Unfortunately, the collisional excitation process, that is much more efficient at exciting lines corresponding to transitions between lowest excited states, is negligibly weak at the excitation of high- n levels. Therefore, emissivities of the RLs are normally several orders of magnitude weaker than those of the collisionally-excited lines, but, as we show in this article, intensities of the recombination lines from the FMKs do reach detectable levels.

For oxygen-dominated knots, using plasma parameters (electron temperature, density and emission measure of the gas at different distances from the shock wave) from the SD95 model with a 200 km s^{-1} shock speed we have computed the spectrum in the optical and near-infrared bands accessible by modern ground-based telescopes. The cloud shock speed in the Cas A FMKs of about 200 km s^{-1} is determined by SD95 from the comparison of observed optical spectra with their model predictions. Although a similar analysis based on the Borkowski & Shull (1990) model would also be valuable, the original article does not give enough information to allow us to compute the RL fluxes (e.g., the ionization state distributions as functions of temperature cannot be resolved from the plots in the regions significantly contributing to the recombination line emission).

The lines under consideration are predicted to be 200–1000 times weaker than e.g. the [O III] line at 5007 Å. However, their fluxes are well above the sensitivity of the best present-day telescopes. These fluxes are only 2–5 times weaker than the detection limits of observations done in the 1970s and later, on the 200-inch and smaller telescopes (Peimbert & van den Bergh 1971; Chevalier & Kirshner 1979; Hurford & Fesen 1996). Observations of these lines do not demand high spectral resolution due to velocity spreads and turbulence in the shocked plasma, as well to intrinsic line splitting.

The recombination lines discussed below are radiated by all coexisting ionized oxygen species, from O^+ to O^{6+} . Study of these lines will permit us to observe in detail the process of the non-equilibrium cooling and recombination of the pre- and post-shock plasmas overabundant in oxygen or sulphur and silicon.

The discussed spectral lines allow us to observe the coldest ionized pre-shock and post-shock regions in the FMK, that are not detectable using the ground-based observations by any other means. The fine-structure far-infrared emission lines are also able to give such information, but demand an observatory located outside the atmosphere and cannot reach angular resolutions sufficient to distinguish individual knots.

Observations of recombination lines of elements other than oxygen will allow us to improve our knowledge of many yet unknown physical parameters characterizing the Cas A ejecta.

The metal recombination lines are a promising tool also for studies of other oxygen-rich supernova remnants like Puppis A, N132D, G292+1.8, etc.

The paper structure is the following. In the second section we describe our method of recombination line flux computation. In Sect. 3 we apply the method to predict the optical and near-infrared line fluxes from the optical knots in Cassiopeia A and compare them with existing observational constraints. A description of the recombination line substructure allowing one to identify the parent ion is given in the Sect. 4. In Sect. 5 we discuss ways to obtain information about physical parameters of the emitting region from the line ratios. In Sect. 6 we conclude.

2. Computation of recombination line fluxes

In the process of radiative recombination, especially at low temperatures (when kT is at least several times below the ionization potential), a significant part of the electrons recombine into excited states. Dielectronic recombination for the majority of heavy ions populate excited states even more efficiently than radiative recombination.

In low-density plasmas, such recombination into excited states, characterized by quantum numbers (nl), is followed by the electron radiative cascade to the ground state and emission of multiple photons in the course of the cascade. In the case of recombining highly-charged ions, these photons are emitted in microwave, infrared, optical and ultraviolet spectral bands.

In this paper we describe the lines produced as a result of such a radiative cascade, when both collisional and induced transitions of the type $(nl) \rightarrow (n'l')$ are unimportant. The only non-radiative process influencing the electron cascade in our model is the collisional $(nl) \rightarrow (n'l')$ transitions, as they have much higher cross sections and more significantly affect the level populations at relatively low n . They also are the main reason for changes of the recombination line emissivities with electron density.

We show in Appendix A that the n -changing transitions may be neglected in computations of optical recombination line fluxes, while still retaining reasonable accuracy of the results (better than 20%).

2.1. Elementary processes

In the current work we account for the following processes:

- Radiative recombination (RR). Its level-specific rates $q_{RR}(nl; T_e)$ were computed as described in Appendix B.1.
- Dielectronic recombination (DR). Its level-specific rates $\sum_{\gamma} q_{DR}(\gamma, nl; T_e)$ were computed as described in Appendix B.2.
- Radiative transitions. Their rates $A_{nl, n'l'}$ were computed using hydrogenic formulae with radial integral expressions from Gordon (1929). This may not be accurate for non-hydrogenic ions at $l < 3$, but electrons recombined to those low- l states mostly transit to $n' \approx l$ and do not contribute to the optical RL emission¹.
- Collisional l -redistribution. Its rates $C_{nl, n'l'}$ were computed using sudden collision approximation expressions from Pengelly & Seaton (1964) and Summers (1977), in the region of their applicability. Outside it (where the maximum cut-off parameter r_{\max} becomes less than the minimum one r_{\min}), we approximated the Vrinceanu & Flannery (2001) classical expressions introducing a cut-off at large impact parameters equal to r_{\max} . Details of this approximation are of minor importance, since the cross sections are proportional to r_{\max}^2 , therefore being relatively small. Energies of (nl) -levels and their differences determining the collisional rates in many cases were computed as described in Appendix B.4.

The usage of the hydrogenic approximation does not allow us to reliably compute emissivities and wavelengths of the lines corresponding to transitions involving levels $n < 4$. Therefore we do not provide the results concerning these levels.

Details of the atomic physics and approximations utilized for computations of the line emissivities are given in Appendix B.

2.2. Cascade and l -redistribution equations

The equation describing the radiative cascade of a highly-excited electron, accounting for the collisional l -redistribution, is

$$N_{nl} \left(\sum_{n' < n} \sum_{l' = l \pm 1} A_{nl, n'l'} + \sum_{l' \neq l} C_{nl, n'l'} \right) = n_e n_+ \left(q_{RR}(nl) + \sum_{\gamma} q_{DR}(\gamma, nl) \right) + \sum_{n' > n} \sum_{l' = l \pm 1} N_{n'l'} A_{n'l', nl} + \sum_{l' \neq l} N_{n'l'} C_{n'l', nl}, \quad (1)$$

where n_e , n_+ and N_{nl} are the number densities of electrons, recombining ions and recombined ions with electrons on the level (nl) .

An analytic solution of this coupled system of equations involves inversion of large matrices of sizes of up to several tens of thousands and is not feasible.

We solved the problem the following way. Starting from some maximum $n = n_{\max}$ relevant for the problem (defined in Appendix A), we neglected its cascade population. Knowing the level-specific recombination and l -redistribution rates, we computed the resulting populations of levels (nl) by numerical solution of the system of linear Eq. (1) for $n = n_{\max}$.

Using level-specific radiative rates, we could compute the l -resolved cascade population of the levels (nl) for $n = n_{\max} - 1$.

¹ After all computations were performed, we learnt about a more elegant and modern way of hydrogenic radial integral computation using associated Laguerre polynomials (Malik et al. 1991; note that there is a typographical error in one of their equations, which is rectified in the Appendix of Heng & McCray 2007).

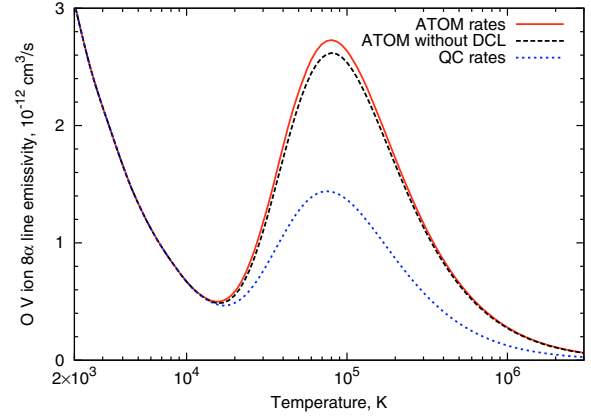


Fig. 1. Temperature dependence of the O V 8α recombination line emissivity in the low-density limit. The lower curve corresponds to DR rate computations using quasi-classical autoionization rates, the upper curve – to the ATOM rates (for details see Appendix B.2), the middle curve does not account for the process of line emission without recombination (DCL), described in Appendix B.6. At low temperatures the emissivity increase is determined by the radiative recombination, but the peak around 10^5 K arises due to the dielectronic recombination.

Having computed total population rates, we solved the system (1) for this n . In such a way, moving downwards in n , populations of all levels were computed.

2.3. Recombination line emissivities

Having obtained level populations N_{nl} , we computed recombination line emissivities $\varepsilon(nl, n'l')$, cm^3/s , defined as

$$\varepsilon(nl, n'l') = \frac{dN(nl \rightarrow n'l')}{dVdt} \frac{1}{n_e n_+} = \frac{N_{nl}}{n_e n_+} A_{nl, n'l'}, \quad (2)$$

where $dN(nl \rightarrow n'l')/dVdt$ is the number of transitions from level (nl) to $(n'l')$ per second in the unit volume.

As an example, the predicted O V 8α line² low-density emissivity with l - and l' -components summed is shown in Fig. 1 as a function of temperature for different approximations.

Emissivities of recombining O⁵⁺ optical and near-infrared recombination lines are given in Table 1 as functions of temperature in the low-density limit.

Approximate wavelengths³ of the brightest lines of all ions as functions of ionization stage are given in Table 2. They can be easily estimated using hydrogenic expressions for any recombination line arising in transition $n \rightarrow n'$ between levels with $n' > 3$, $l > 2$ as

$$\lambda(n \rightarrow n') \approx \frac{0.091127}{Z^2} \left(\frac{1}{n'^2} - \frac{1}{n^2} \right)^{-1} \mu\text{m}, \quad (3)$$

where Z is the recombining ion charge.

2.4. Resulting line fluxes

Fluxes $I(nl, n'l')$, $\text{erg}/\text{cm}^2/\text{s}$, of the lines were computed by integrating along the line of sight

$$I(nl, n'l') = h\nu \frac{S}{4\pi R^2} \int \varepsilon(nl, n'l'; T_e(r)) n_e(r) n_+(r) dr, \quad (4)$$

² As usual, by $n\alpha$ we denote a spectral line formed by electronic transition from level $n + 1$ to level n , by $n\beta$ – from $n + 2$ to n , etc.

³ Here and everywhere below we present the vacuum wavelengths.

Table 1. Wavelengths λ and emissivities ε of several O V optical and near-infrared recombination lines in the low-density limit.

Line	$\lambda, \mu\text{m}$	Emissivity $\varepsilon, \text{cm}^3/\text{s}$, for electron temperature T_e			
		$1 \times 10^3 \text{ K}$	$3 \times 10^3 \text{ K}$	$1 \times 10^4 \text{ K}$	$3 \times 10^4 \text{ K}$
5 α	0.298	9.4×10^{-12}	4.1×10^{-12}	3.5×10^{-12}	5.9×10^{-12}
6 α	0.495	7.6×10^{-12}	3.2×10^{-12}	1.2×10^{-12}	3.0×10^{-12}
7 α	0.762	6.3×10^{-12}	2.5×10^{-12}	8.8×10^{-13}	1.9×10^{-12}
8 α	1.112	5.2×10^{-12}	2.0×10^{-12}	6.7×10^{-13}	1.3×10^{-12}
9 α	1.554	4.4×10^{-12}	1.7×10^{-12}	5.2×10^{-13}	8.8×10^{-13}
10 α	2.100	3.7×10^{-12}	1.4×10^{-12}	4.1×10^{-13}	6.0×10^{-13}
11 α	2.761	3.2×10^{-12}	1.1×10^{-12}	3.3×10^{-13}	4.0×10^{-13}
12 α	3.548	2.7×10^{-12}	9.3×10^{-13}	2.6×10^{-13}	2.6×10^{-13}

Table 2. Hydrogenic vacuum wavelengths, μm , of some optical and near-infrared recombination α -lines for several ionization stages, denoted by the ion spectroscopic symbol after recombination.

Line	I	II	III	IV	V	VI
4 α	4.0501	1.0125	0.4500	0.2531	0.1620	0.1125
5 α	7.4558	1.8640	0.8284	0.4660	0.2982	0.2071
6 α	12.365	3.0913	1.3739	0.7728	0.4946	0.3435
7 α	19.052	4.7629	2.1168	1.1907	0.7621	0.5292
8 α	27.788	6.9471	3.0876	1.7368	1.1115	0.7719
9 α	38.849	9.7122	4.3165	2.4281	1.5540	1.0791
10 α	52.506	13.127	5.8340	3.2817	2.1003	1.4585
11 α	69.035	17.259	7.6705	4.3147	2.7614	1.9176
12 α	88.707	22.177	9.8563	5.5442	3.5483	2.4641

where $h\nu$ is the photon energy, R is the distance from the observer to the emitting region and S is the emitting region area.

The integral over distance in the plane-parallel approximation can be easily transformed into an integral over temperature by substitution

$$dr = \frac{dr}{dt} \frac{dt}{dT} dT = v_{\text{shock}} \frac{n_{0,t}}{n_t} \frac{3/2(n_t + n_e)k_B}{n_t n_e \Lambda_N} dT,$$

where v_{shock} is the shock front speed, Λ_N is a cooling function and n_t and $n_{0,t}$ are the total number densities of all ions in a given point and in the pre-shock region.

The parameters of this equation – cooling function, electron and ion densities as functions of temperature – were taken from the SD95 200 km s⁻¹ shock model, described in more detail in Sect. 3 below.

For the purpose of qualitative analysis, we introduce below the oxygen differential emission measure per logarithmic temperature interval

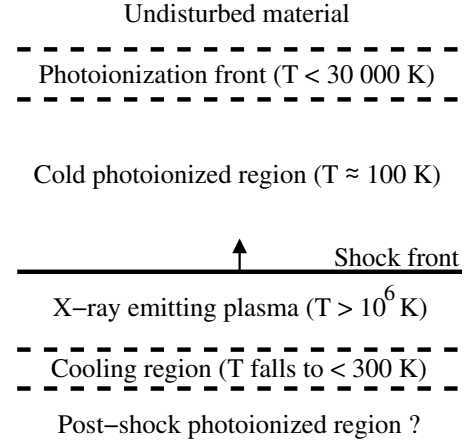
$$\frac{dE_O}{d(\log T_e)} = T_e \frac{n_O n_e dr}{dT_e},$$

where n_O is the total oxygen ion number density. It shows the contribution of a given logarithmic temperature interval to the total emission measure, showing where most of the line emission originates. Using this notion, we can express the line flux from Eq. (4) as

$$I(nl, n'l') = hv \frac{S}{4\pi R^2} \int \varepsilon(nl, n'l'; T_e) \frac{dE_O}{d \log T_e} \frac{n_+}{n_O} T_e dT_e.$$

Here the fraction n_+/n_O is the abundance of a given ionic species and is also dependent on temperature.

In our computation of the post-shock recombination line emission, we artificially stop integrating expression (4) when the plasma temperature drops below 1000 K. This results in some,

**Fig. 2.** The plane-parallel SD95 model schematic structure. The drawing is not to scale. Arrow shows the shock wave direction. Optical lines are emitted from the photoionization front and the post-shock cooling region at temperatures of several tens of thousands Kelvin. Recombination lines arise in the cold photoionized region and the post-shock cooling region.

possibly significant, underestimation of the cooling region line fluxes arising from recombinations of O²⁺ ions. However, as we show below, the O II recombination lines from the photoionized region are expected to be much brighter.

It should be remembered that, e.g., O V recombination lines arise in the radiative cascade in the O⁴⁺ ion triggered by the recombination of the O⁵⁺ ion, so the line fluxes are proportional to the ionic abundance of O⁵⁺, not O⁴⁺.

3. Astrophysical application: FMKs in Cassiopeia A

The SD95 model describes fast-moving knot emission as arising in the interaction of the oxygen-dominated dense cloud with the external shock wave, entering the cloud and propagating through it (see Fig. 2). The heated region just after the shock front produces a high flux of ionizing radiation that results in the appearance of two photoionized regions: before and after the shock front.

The plasma after the shock front passage cools rapidly and, at temperatures of $(0.5-5) \times 10^4$ K, emits the lines observable in the visible and near-infrared spectra (Chevalier & Kirshner 1978, 1979; Hurford & Fesen 1996; Gerardy & Fesen 2001). The thickness of this emitting layer is extremely small (about 10¹⁰–10¹¹ cm), but due to the high density of the cooling material at $T < 10^5$ K it is able to contribute to production of bright emission lines of highly-ionized atomic species, such as [O III]. This region also gives rise to the recombination line (RL) emission.

The SD95 model does not include the photoionized region after the shock front. Until now, even the presence of this region has been disputed (Itoh 1986) because, if present, it would produce too bright optical lines of neutral oxygen.

Between the photoionization front and the shock wave the plasma is predicted to be extremely cold ($T_e < 10^3$ K) and rather highly ionized (ionic abundances of O³⁺ and O²⁺ are about 60% and 30% in the SD95 200 km s⁻¹ shock model). This cold ionized region, invisible in optical and X-ray bands, should be actively recombining and emitting bright recombination lines.

The resulting RL emission computed based on the SD95 200 km s⁻¹ shock model is described separately in the following subsections for each of these two regions: after and before the shock front.

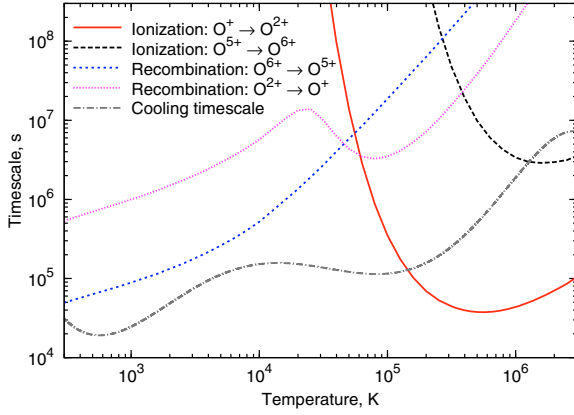


Fig. 3. Oxygen ion O^{6+} and O^{2+} recombination and ionization timescales compared to the plasma cooling time using the electron density dependence on temperature and the cooling function from the SD95 model with a 200 km s^{-1} cloud shock speed.

In this section we provide results on the l -summed recombination line fluxes, whereas in the Sect. 4 we discuss in detail the individual line spectral substructure that separates in some cases the recombination lines into several components, thus diminishing the individual component fluxes by up to factors of 2–4.

3.1. Cooling region after the shock front

It is useful to make order-of-magnitude estimates of some timescales in the post-shock rapidly cooling plasma at temperatures between several hundred and $3 \times 10^4 \text{ K}$, where the recombination line emission occurs (see below). As derived from the SD95 model, the plasma cooling time is roughly equal to

$$\tau_{\text{cool}} = \frac{3(n_t + n_e)kT_e}{2n_t n_e \Lambda} \approx 2 \times 10^4 \text{ s } T_4^{1/2} n_{t,5}^{-1},$$

where $T_e = 10^4 T_4 \text{ K}$ and $n_t = 10^5 n_{t,5} \text{ cm}^{-3}$. It should be compared with the time needed to reach the collisional ionization equilibrium (CIE), that is in our case approximately equal to the recombination timescale τ_{rec} . For example, for ion O^{2+} and O^{6+} the recombination time is

$$\tau_{\text{rec}}(O^{6+}) = (n_e q_{\text{RR}, O^{6+}}(T_e))^{-1} \approx 4.7 \times 10^5 \text{ s } T_4^{0.64} n_{e,5}^{-1},$$

$$\tau_{\text{rec}}(O^{2+}) = (n_e q_{\text{RR}, O^{2+}}(T_e))^{-1} \approx 4.9 \times 10^6 \text{ s } T_4^{0.64} n_{e,5}^{-1},$$

where $n_e = 10^5 n_{e,5} \text{ cm}^{-3}$ and $q_{\text{RR}, O^{2+}}$ is the total radiative recombination rate for this ion, taken from Pequignot et al. (1991). It is easy to see that the recombination timescale in this temperature interval is always longer than the cooling time for any abundant ion. Therefore the plasma is strongly overionized for its temperature, which results in high emissivities of the recombination lines.

The quantitative comparison of these timescales in the model is given in Fig. 3, where ionization and recombination timescales for several ions are compared with the cooling time. At high temperatures the cooling timescale is longer than the ionization timescales and the material has enough time to converge to the CIE. At $T_e < 10^6 \text{ K}$ the cooling is much faster than the recombination down to temperatures of several hundred Kelvin and the high ionization state stays “frozen” until very low temperatures are reached.

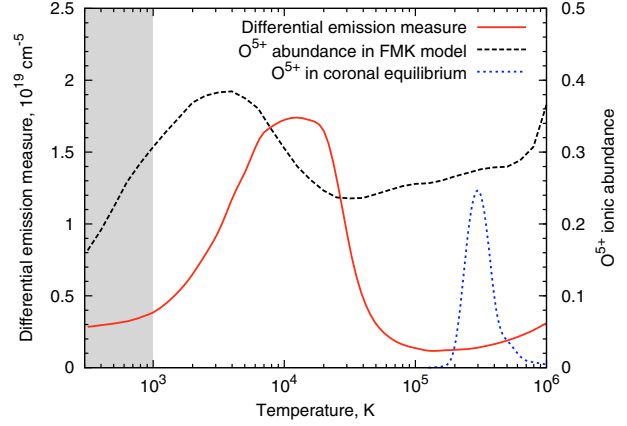


Fig. 4. Differential oxygen emission measure per logarithmic temperature interval $dE_O/d(\log T_e)$ in the post-shock cooling region of the SD95 FMK model. Ionic abundances $n(O^{5+})/n(O)$ of the O^{5+} ion in the FMK model and in the collisional ionization equilibrium in low-density plasmas (Mazzotta et al. 1998) are also shown. The temperature range not taken into account in our calculations is shaded.

Let us now compare the thermalization timescales and mean free paths to the quantities determined above. Following Spitzer (1956), the electron or ion self-collision timescale is equal to

$$\tau_c = 114 \text{ s } \frac{A^{1/2} T_4^{3/2}}{n_5 Z^4 \ln \Lambda_C},$$

where A is the atomic weight (equal to $m_e/m_p \approx 1/1836$ for electrons), Z is the particle charge, $n = 10^5 n_5 \text{ cm}^{-3}$ is the particle concentration and $\Lambda_C \approx 3.92 \times 10^7 n_{e,5}^{-1/2} T_4^{3/2}$. In our case of the highly-charged plasma having $Z \gg 1$ the timescale of the ion-ion collisions is even shorter than for the electron-electron collisions.

Nevertheless, the mean free path even for electrons λ_e stays significantly below any other characteristic scale, including the typical temperature change length scale of the order of $10^9 - 10^{10} \text{ cm}$:

$$\lambda_e = \tau_{c,e} \sqrt{3kT_e/m_e} \approx 1 \times 10^7 \text{ cm } T_4^2 n_{e,5}^{-1}.$$

For an illustration of the characteristic conditions after the passage of the shock front, in Fig. 4 we show the Li-like O^{5+} ion density as function of plasma temperature for this region⁴. The figure demonstrates overly high abundance of this ion in relatively dense plasma with $T < 3 \times 10^4 \text{ K}$ after the shock front, much higher than in the CIE, where this ion exists only in a narrow temperature range $T_e = (2-7) \times 10^5 \text{ K}$ (Mazzotta et al. 1998).

In the same figure we also present the oxygen emission measure distribution over temperature $d(EM)/d(\log T_e)$ in the SD95 model. This distribution together with the line emissivity dependence on temperature (e.g., Fig. 1) allows one to calculate the relative contributions to the total line flux from different temperature intervals (see Sect. 2.4 above).

⁴ We made our own computations of the post-shock plasma recombination and discovered that our oxygen ion distribution over ionization stages is rather similar to the one presented in the lower panel of Fig. 3 of SD95, but only if the ion spectroscopic symbols on that figure are increased by unity. Therefore we assume that Fig. 3 of SD95 has a misprint and the ion spectroscopic symbols should be read, e.g., “O VII” instead of “O VI”, “O VI” instead of “O V”, etc.

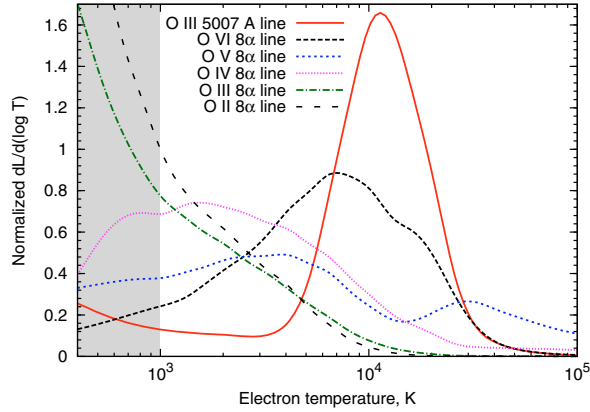


Fig. 5. Differential luminosity distribution per logarithmic temperature interval according to the SD95 model for several spectral lines, including the prominent 5007 Å [O III] line and predicted O II–O VI 8α lines. Curves are normalized so that the area enclosed under each of them equals one. The temperature range not taken into account in our calculations is shaded.

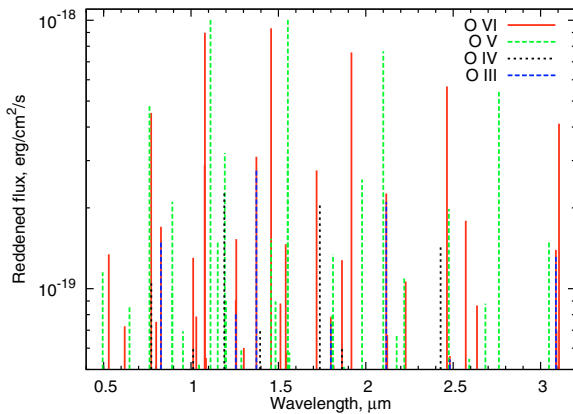


Fig. 6. Reddened recombination line l -summed fluxes F from the post-shock cooling region. Details are as in note to Table 3. Here the lines are represented as “infinitely thin”; their fine structure is discussed in Sect. 4.

Such line flux distributions for the prominent [O III] line at 5007 Å and 8α recombination lines of different oxygen ions are shown in Fig. 5. Note that at low temperatures (below 4000 K), the [O III] 5007 Å line emission is dominated by the contribution from the recombination cascades, not the collisional excitation. The cascade contribution to the post-shock intensity of this line reaches about 20%.

Because of high O^{6+} abundances at both low and high temperatures, the distribution of the O VI 8α line emission is much wider than that of the collisionally-excited optical [O III] line and has 90% of its area within the temperature range $5 \times 10^2 - 2 \times 10^4$ K. Note that the dielectronic recombination contributes less than 30% to the resulting line intensity for any of the oxygen ions in the discussed SD95 model.

The O V and O VI lines are the brightest expected ones. Lines of O III and O IV from this region are predicted to be dimmer by a factor of about three, and the O II lines by a factor of about ten.

In Fig. 6 we show the predicted oxygen recombination line fluxes from the post-shock region of a model FMK. The brightest recombination lines around 1 μm are about 2000 times less intense than the reddened [O III] 5007 Å line. Expected flux values are given in Table 3.

Table 3. Brightest recombination line l -summed emitted and reddened fluxes I and F from the post-shock cooling region computed following the SD95 model. The optical [O III] 5007 Å line flux is also given. The last column contains the flux part in the strongest unresolved line component f_s . The wavelength λ corresponds to the strongest line component.

Ion	Line	λ , μm	I , erg/cm ² /s	F , erg/cm ² /s	f_s
O VI	7α	0.5293	1.16×10^{-17}	1.34×10^{-19}	0.99
O VI	8α	0.7720	7.73×10^{-18}	4.52×10^{-19}	0.99
O VI	9α	1.0792	4.32×10^{-18}	8.98×10^{-19}	1.31*
O VI	12β	1.3740	9.15×10^{-19}	3.10×10^{-19}	0.99
O VI	10α	1.4586	2.52×10^{-18}	9.32×10^{-19}	1.00
O VI	13β	1.7189	6.18×10^{-19}	2.76×10^{-19}	1.00
O VI	11α	1.9177	1.54×10^{-18}	7.58×10^{-19}	1.00
O VI	12α	2.4642	9.69×10^{-19}	5.69×10^{-19}	1.00
O V	6α	0.4943	1.82×10^{-17}	1.14×10^{-19}	0.62
O V	7α	0.7618	8.68×10^{-18}	4.89×10^{-19}	0.81
O V	8α	1.1114	4.53×10^{-18}	1.01×10^{-18}	0.89
O V	10β	1.1929	1.22×10^{-18}	3.20×10^{-19}	0.92
O V	9α	1.5538	2.51×10^{-18}	1.00×10^{-18}	1.21*
O V	12β	1.9784	5.05×10^{-19}	2.55×10^{-19}	0.96
O V	10α	2.1002	1.45×10^{-18}	7.65×10^{-19}	0.94
O V	11α	2.7613	8.72×10^{-19}	5.43×10^{-19}	0.97
O IV	7α	1.1902	8.82×10^{-19}	2.32×10^{-19}	0.80
O IV	8α	1.7363	4.58×10^{-19}	2.07×10^{-19}	0.74
O III	5α	0.8262	1.88×10^{-18}	1.42×10^{-19}	0.25
O III	6α	1.3727	8.23×10^{-19}	2.78×10^{-19}	0.25
O III	7α	2.1149	3.96×10^{-19}	2.10×10^{-19}	0.76
[O III]		0.5007	5.78×10^{-15}	3.90×10^{-17}	
[O III]**		0.5007	2.72×10^{-13}	1.84×10^{-15}	

* Including the 11β line that overlaps with 9α.

** Including the pre-shock photoionized region contribution.

Note. Assumed cloud area is 1×10^{34} cm (size about 2''). Reddening was applied using the Schild (1977) reddening curve and $E(B-V) = 1.5$ (Hurford & Fesen 1996). The brightest knots are a factor of 5–20 more intense in the [O III] 5007 Å line than the values given in the table. The f_s values were determined from simulated spectra having a 200 km s⁻¹ Doppler line width at the half maximum level ($FWHM$), that is equal to the optical line widths observed in the Cas A knots (van den Bergh 1971); see also Sect. 4.

3.2. Cold photoionized region

The ions in the photoionized region before the shock front are rapidly recombining because of their low temperature. This results in rather bright recombination lines, with fluxes proportional to the distance d between the ionization front and the shock wave.

The plane-parallel SD95 model does not determine this distance. The assumption of small optical depth of material between the shock wave and the ionization front results in restriction of $d < 10^{17}$ cm for relevant cloud models for a preshock ion number density of 100 cm⁻³ (illustrated in Fig. 12 of SD95). Below we conservatively take $d = 10^{15}$ cm, keeping in mind that the line fluxes scale linearly with it.

The cloud model also does not determine the exact temperature in the photoionized region. We take $T_e = 1 \times 10^3$ K as a reference value, but Dopita et al. (1984) mention that it may be as low as 100 K. If the real temperature in the region is less than our assumed value, recombination line emissivities are respectively higher (see Sect. 5.1 below for quantitative dependences).

Predicted oxygen line fluxes for the SD95 model OP200 with a shock speed of 200 km s⁻¹ and total preshock ion number

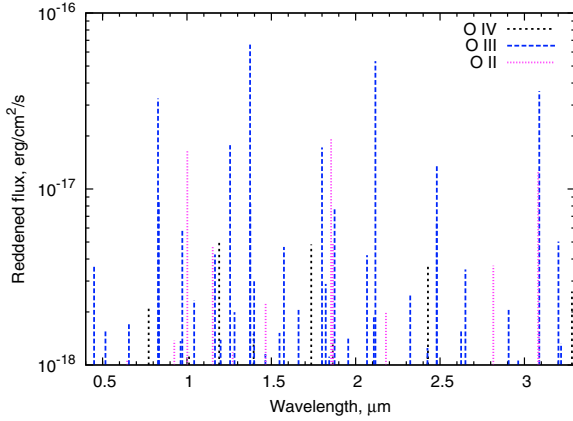


Fig. 7. Recombination line l -summed reddened fluxes expected from the photoionized region before the shock front computed following the SD95 ionization front model. Details are as in the note to Table 3. The photoionized region thickness is 10^{15} cm.

Table 4. Brightest recombination line l -summed emitted and reddened fluxes I and F from the photoionized region before the shock front, computed following the SD95 model. Details are as in the note to Table 3. The photoionized region thickness is 10^{15} cm. The last column contains the flux part in the strongest unresolved line component f_s for a $FWHM$ of 200 km s^{-1} (see Note to Table 3). The wavelength λ corresponds to the strongest line component.

Ion	Line	$\lambda, \mu\text{m}$	$I, \text{erg/cm}^2/\text{s}$	$F, \text{erg/cm}^2/\text{s}$	f_s
O III	5α	0.8262	4.13×10^{-16}	3.26×10^{-17}	0.26
O III	6β	0.8327	1.05×10^{-16}	8.48×10^{-18}	0.31
O III	7β	1.2552	6.09×10^{-17}	1.77×10^{-17}	0.73
O III	6α	1.3727	1.95×10^{-16}	6.61×10^{-17}	0.27
O III	8β	1.7998	3.69×10^{-17}	1.72×10^{-17}	0.86
O III	7α	2.1149	1.00×10^{-16}	5.32×10^{-17}	0.82
O III	9β	2.4804	2.32×10^{-17}	1.36×10^{-17}	1.32*
O III	8α	3.0871	5.50×10^{-17}	3.59×10^{-17}	0.91
O II	5α	1.8645	4.03×10^{-17}	1.94×10^{-17}	0.24
O II	6α	3.0922	1.90×10^{-17}	1.24×10^{-17}	0.59

* Including the 10γ line that overlaps with 9β .

density of 100 cm^{-3} are shown in Fig. 7 and given in Table 4. It is seen that even with our quite conservative assumptions, the resulting line fluxes are noticeably stronger than from the shock front. Indeed, the predicted line brightest components are on the level of a percent of the [O III] 5007 Å line.

If this would be the case, the lines would have been detected in spectroscopic observations of the fast-moving knots (see discussion on existing observation limits in Sect. 3.4 below).

Our estimate of the observational limit on the O III 5α recombination line flux at $0.83 \mu\text{m}$ based on the data by Hurford & Fesen (1996) of $0.005 \times F(5007 \text{ \AA})$ may be transformed into a joint constraint on the thickness of the photoionized region d , its temperature T_e and total ion density n_t :

$$\left(\frac{n_t}{100 \text{ cm}^{-3}}\right)^2 \left(\frac{10^3 \text{ K}}{T_e}\right) \left(\frac{d}{10^{15} \text{ cm}}\right) < 1,$$

assuming $E(B - V) = 1.5$ and O^{3+} ionic abundance after the ionization front of 0.6.

From this example it is easy to see that detection of the lines or even tight upper limits will allow us to perform detailed observational tests of the SD95 and other FMK models.

3.3. Separating pre- and post-shock spectral lines

Observationally, the lines formed in the regions before and after the shock wave will be distinguishable because of two effects. Firstly, the lines arising in the photoionized region still dynamically undisturbed by the shock wave should be very narrow intrinsically, but the lines arising in the post-shock region are expected to be Doppler-broadened by turbulence.

Secondly, the spectral lines arising in the post-shock region should be shifted with respect to the pre-shock lines. The relative Doppler shift between these two line families appears due to motion of the post-shock gas relative to the initial knot speed induced by the shock wave. In the strong-shock limit this velocity difference equals $3/4 v_{\text{shock}}$ for the specific heat ratio $\gamma = 5/3$ (Zel'dovich & Raizer 1967), i.e. up to 150 km s^{-1} in the SD95 model, but the relative Doppler shift will also depend on the angle between the shock front and the direction towards the observer.

Both collisionally-excited and recombination lines should display these features, but for the former group such differences should be easier to detect because of their higher line intensities.

The observations with higher spectral resolution ($\lambda/\Delta\lambda \lesssim 20\,000$) could also result in detection of several narrow components forming a line. They could arise from the individual vortice or velocity component emission, if there is only one or a few of them dominating the plasma motion after the shock, as observed in laser experiments simulating cloud-shock interaction in supernova remnants (Klein et al. 2003). The resulting spectral line profile might be quite complicated (e.g., Inogamov & Sunyaev 2003), but such observations will provide data on the post-shock dynamics of the fast-moving knot that is presently poorly constrained from observations.

3.4. Existing observational limits

As is seen from Figs. 6 and 7, the brightest recombination lines are expected to lie in the wavelength range between 0.7 and $3 \mu\text{m}$. Several detailed spectroscopic investigations have already been performed in this range and could have found these lines, provided that they had low enough detection limits. Below we discuss such existing optical and near-infrared limits on the line fluxes and compare them with the SD95 model predictions.

Optical spectra of fast-moving knots with wide spectral coverage were obtained, e.g., by Chevalier & Kirshner (1979) and Hurford & Fesen (1996). According to the authors, the detection limits around 0.75 – $0.85 \mu\text{m}$ are about 200 – 300 times less than the [O III] 5007 Å line flux for the brightest observed features.

Our results give flux ratios of the reddened 5007 Å line to the brightest components of the O VI 8α , O V 7α and O III 5α lines of about 200 – 2000 (see Figs. 6 and 7 and Tables 3 and 4). These values show that the model is on the boundary of consistency with the observational results. They also imply that oxygen recombination line detection should be possible, provided that the physics in the post-shock and pre-shock regions corresponds to that described by the SD95 model.

Recently, near-infrared (0.95 – $2.5 \mu\text{m}$) spectra of Cas A fast-moving knots, obtained with the 2.4 m Hiltner telescope, were published by Gerardy & Fesen (2001). It is more difficult to compare their detection limits with our predictions, as there is only one oxygen O I line blend present around $1.129 \mu\text{m}$. It arises in transitions between excited states of neutral oxygen and is also blended with the [S I] line. If we assume that the overlapping [S I] line emission is negligible, our estimate of the observational detection limit corresponds to about $1/100$ of the reddened

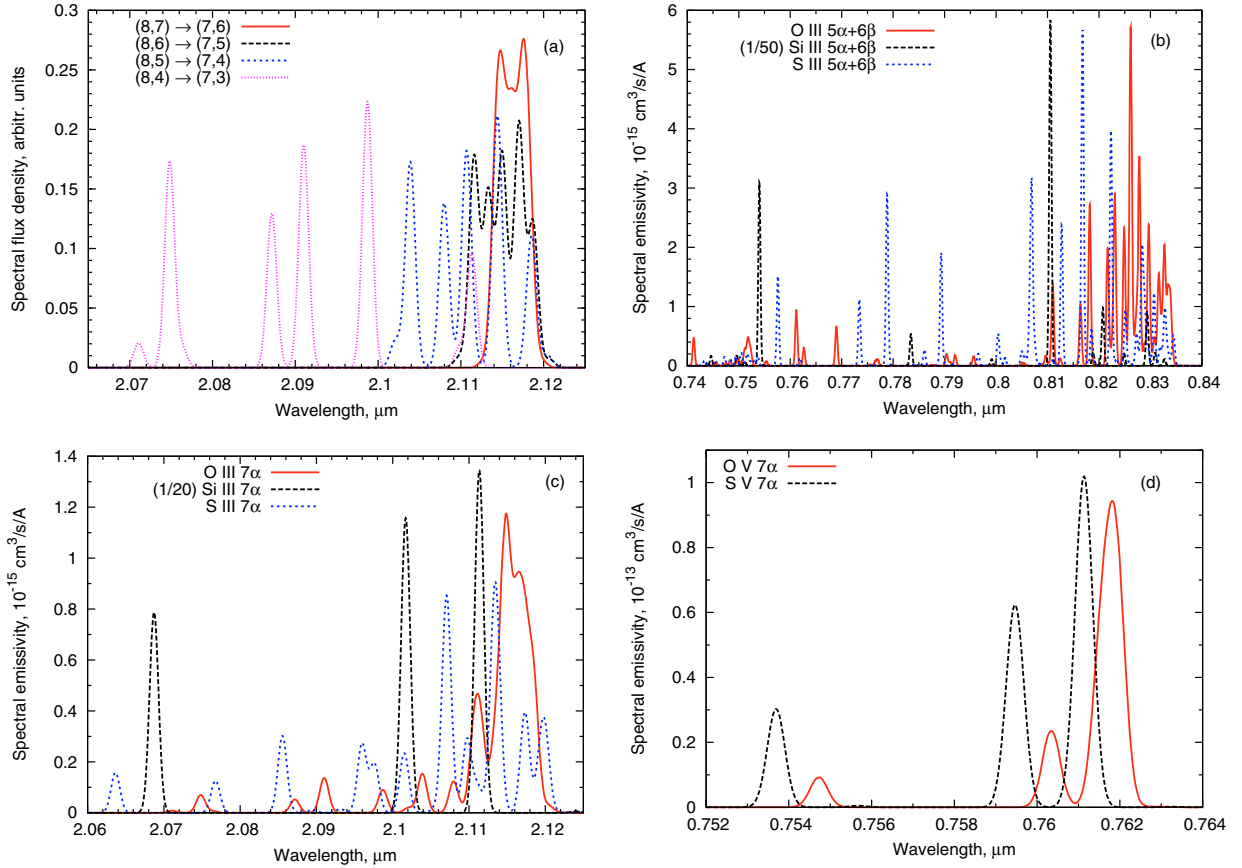


Fig. 8. Fine structure of recombination lines. A Doppler $FWHM$ of 200 km s^{-1} is assumed. **a)** O III 7α line $(8, l) \rightarrow (7, l-1)$ component structure for $l \geq 4$. The sum of all components is set to be equal for each l . Emissivities of the $(8, l) \rightarrow (7, l+1)$ components are much weaker and the structure of the resulting lines is not shown. **b), c)** Spectral emissivity $d\epsilon/d\lambda$, $\text{cm}^3/\text{s}/\text{\AA}$ of the simulated O III, Si III and S III $5\alpha + 6\beta$ and 7α line structure for low-density case and temperature $T_e = 2 \times 10^4 \text{ K}$. Note that Si III lines have been scaled down to fit on the same scale. **d)** Spectral emissivity for the simulated O V and S V 7α line structure in the same conditions. Absence of K -splitting results in much simpler profiles.

optical [O III] line flux. This value is again similar to or a factor of several higher than the predicted fluxes of the O VI 9α , O V 8α and O III 6α and 7α lines, also showing the feasibility of the line detection.

4. Individual line substructure

In the non-relativistic hydrogenic approximation, level energies depend only on the ion charge and the principal quantum number n of the level. Though, this approximation is not fully applicable for the description of the spectral lines corresponding to transitions between the levels with $n \approx 10$, as other effects start playing a role. They arise due to energy level shifts, described in Appendix B.4, resulting in the “fine” structure appearing in the spectral lines. As a result, these effects help to distinguish lines of different elements having equal ionization stages and initial and final ns .

We calculated the line l - and K -substructure following the method outlined in Appendix B.5 (K is the quantum number used to characterize additional interaction of the highly-excited electron orbital momentum with the total angular momentum of other electrons, present in O II, O III, S II and S III lines). The results are shown in Fig. 8 for the most interesting cases, assuming recombination lines having widths around 200 km s^{-1} (full width at half maximum level, $FWHM$), of the same order as the observed widths of forbidden optical lines (van den Bergh 1971).

It is easily seen that high- l levels have both smaller quantum defects and smaller K -splitting. When K -splitting is present, a complicated line structure results in weaker individual line fluxes, making them more difficult to detect.

The spectral lines arising in the transitions between lower- n levels have higher K - and l -splittings. Therefore the line components have larger separations and the number of individual components increases even more, with each of them being less intense. The near-infrared lines are therefore more promising for the detection than the optical ones, as they have less substructure (compare panels (b) and (c) in Fig. 8).

The substructure of the 6α recombination lines of Mg I, Al I and Si I have been observed in solar spectra near $12 \mu\text{m}$ and explained using similar, although somewhat more elaborate, theoretical descriptions (Brault & Noyes 1983; Chang & Noyes 1983; Chang 1984). We have used these observations as the test cases for our line substructure computation code.

In Tables 5–15, available as an electronic supplement at CDS, we give O II–O VI, S II–S V, Si II and Si III recombination line component vacuum wavelengths, emissivities and relative intensities in the $(nlK) \rightarrow (n'l'K')$ resolution for several temperatures ($\lg(T_e, \text{K}) = 3.0, 3.5, 4.0, 4.5$ and 5.0) in the low-density limit. The first seven columns characterize the quantum numbers of the transition (total recombining ion electronic angular momentum J_c and highly-excited electron quantum numbers before and after the transition n, l, K, n', l', K'), Col. 8 gives the line component wavelength in microns, the next columns in pairs

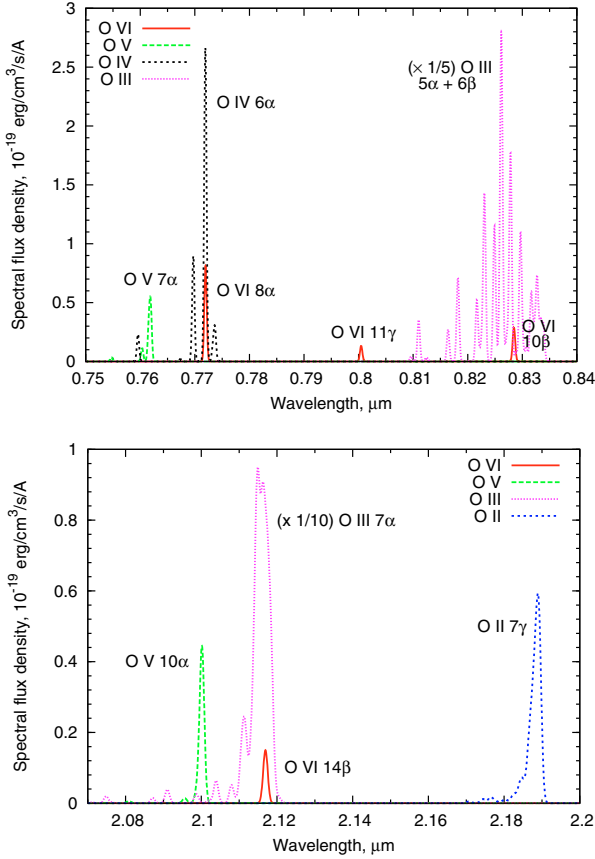


Fig. 9. Model spectra near 0.8 and 2.1 μm containing recombination lines of O II–O VI computed based on the SD95 200 km s^{-1} shock model. Contributions of cooling and photoionized regions are added. It is seen that at longer wavelengths the line profiles are less influenced by the substructure. Note that O III line fluxes are diminished to fit on the same scale. A line $FWHM$ of 200 km s^{-1} is assumed.

give the line component emissivity in cm^3/s and the intensity ratio of this component with respect to the K - and l -summed emissivity $\varepsilon(J_c, n'lK, n'l'K')/\varepsilon(n, n')$. Only the lines most likely to be detected are given in these tables, selected by the following parameters – only α , β and γ lines having wavelengths between 0.3 and 5.0 μm .

Tables 16–23, also available at CDS, contain similar information on predicted oxygen line component fluxes in the SD95 200 km s^{-1} shock model. The fluxes from the cooling and photoionized regions are given separately in Tables 16–20 (for O II–O VI) and 21–23 (for O II–O IV), respectively. The first eight columns again contain the quantum numbers characterizing the transition and the line wavelength, Col. 9 lists the line component flux in $\text{erg/cm}^2/\text{s}$, Col. 10 contains the intensity ratio of this component with respect to the K - and l -summed emissivity.

As discussed in Appendix B.4, the input atomic data are precise to about 10% and we cannot expect better precision of the resulting line wavelength differences from the hydrogenic values.

A sample region from the total resulting model spectrum is shown in Fig. 9. It shows the variety of the spectral shapes as well as illustrates the diminishing of the peak intensity due to K -splitting for O III lines.

The line substructure changes with density and temperature because of changes in the relative populations of the l -states. At low temperatures the main population mechanism is the

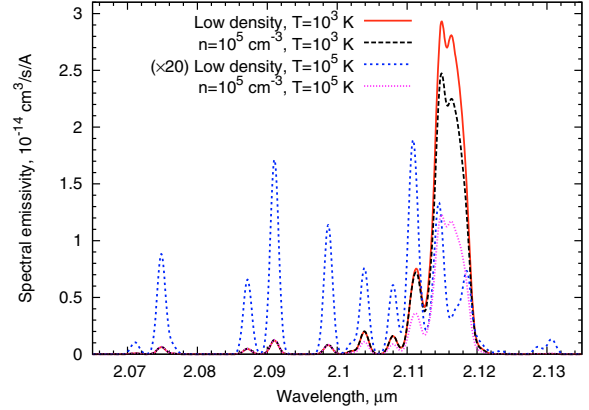


Fig. 10. Variation of the fine structure of the O III 7α line at 2.1 μm with temperature and density. Line $FWHM$ of 200 km s^{-1} is assumed. Note that the low-density curve for $T_e = 10^5$ K is multiplied by 20 to be visible on this scale.

radiative recombination, which is populating high- l levels relatively efficiently. When the electron density increases, l -redistribution modifies high- l populations for n greater than about 20, but for $n < 15$ the changes are generally smaller.

At higher temperatures, DR populates relatively lower l states having higher quantum defects and low probabilities of α -line emission. Therefore a recombination line is split into many components and its emissivity is relatively low. In this case, l -redistribution mostly shifts the recombined electrons to higher- l states, simplifying the line profile and significantly increasing its emissivity.

In Fig. 10 we show the change of the O III 7α line fine structure with temperature and density, illustrating the described effects.

Another effect arising at low temperatures and electron densities is lower populations of excited J_c core states. For O II, O III, S II and S III lines this results in the damping of the K -splitting, as it arises only from recombination of excited ions. All the flux from $(n'lK) \rightarrow (n'l'K')$ components in this case will be redistributed into the central $(nl) \rightarrow (n'l')$ components and only the l -splitting will remain.

5. Plasma diagnostics using recombination lines

5.1. Temperature diagnostics

The line emissivity dependence on temperature is shown for several bright optical and near-infrared oxygen recombination lines in the low-density limit in Fig. 11. Corresponding line wavelengths are given in Table 2 above. This figure allows us to compute the recombination line fluxes for other models of the multi-temperature plasma with an emission measure distribution different from the discussed SD95 model.

The curves in Fig. 11 have two distinct regions. At low temperatures the emissivity is determined by the radiative recombination and changes smoothly from ion to ion. At temperatures higher than several tens of thousands Kelvin the dielectronic recombination starts to dominate the recombination rates (except for the O VI lines due to the absence at low temperatures of dielectronic recombination channels in the He-like ion O^{6+}) and line emissivities of different ions become determined by the lowest excited states of the recombining ion, as described in Appendix B.2. The temperature of the strong emissivity rise is proportional to the typical energy of such excited states. The

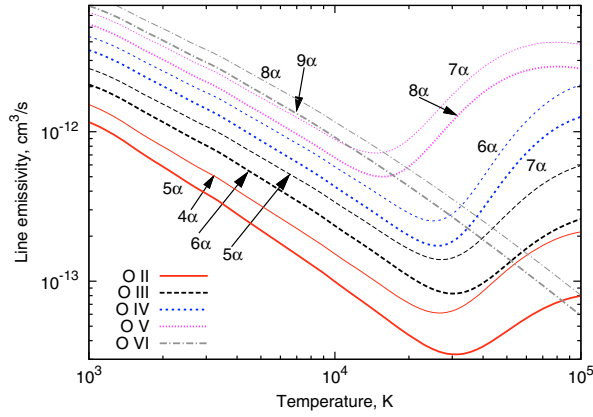


Fig. 11. Low-density l -summed emissivities of oxygen ion optical and near-infrared recombination lines. Different colors represent different ions, plotted line thickness increases with the spectral line wavelength.

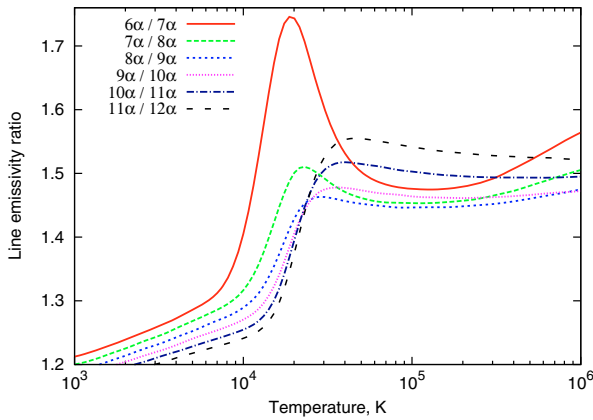


Fig. 12. Low-density l -summed O V recombination line emissivity ratios as functions of electron temperature.

amplitude of the rise is proportional to the lowest excited state decay rate.

For the discussed SD95 200 km s^{-1} shock model the high-temperature region where the DR dominates is important only for O V lines, but it is easy to imagine other ionic abundance distributions where it also will affect ions in lower ionization stages.

The dependence of individual O V recombination α -line ratios on temperature is shown in Fig. 12. Again, the two distinct regions are seen at low and high temperatures corresponding to RR- and DR-dominated recombination.

In the intermediate temperatures, the lines corresponding to transitions at lowest n s become relatively brighter. The reason for such dependence, especially clearly visible in the $6\alpha/7\alpha$ line ratio, is the following. As follows from Appendix B.2, at low temperatures the dielectronic recombination rate is damped by the factor $\exp(-\mathcal{E}/kT_e)$. For the low n levels the doubly excited state energy \mathcal{E} may be significantly lower than the core excitation energy and at low temperatures this makes a difference and the dielectronic recombination populates mostly low- n levels, increasing emissivities of low- n recombination lines.

The described effect is most pronounced for recombination lines of O V, Si III and S V, although in all cases the most temperature-sensitive line – the α -line formed by the transition from the lowest level, into which the DR is possible – is situated around $2000\text{--}3000 \text{ \AA}$. Though, as can be seen from Fig. 12, the next recombination line of these ions around $4500\text{--}5000 \text{ \AA}$ also

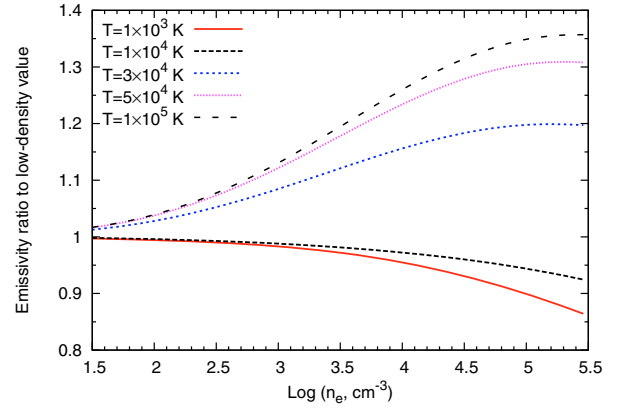


Fig. 13. Dependence of O V 7α line emissivity on electron density for different electron temperatures T_e . Values are normalized to the low-density emissivity.

can be a useful diagnostic tool, being relatively much brighter in a narrow temperature interval.

5.2. Recombination lines as density diagnostics

Recombination line flux ratios in principle allow us also to determine density of the emitting region, as their dependences on density and temperature differently affect the relative line fluxes.

As an example, in Fig. 13 we plot the O V 7α line emissivity as a function of the electron density for different temperatures between 10^3 and 10^5 K. For better representation, emissivity ratios to their low-density values are shown. Clearly, the density dependences are weak and can probably be neglected in the first stage of the qualitative analysis, especially at low temperatures.

Two distinct regions are seen once again. At low temperatures where only radiative recombination determines the level populations, emissivities decrease with density, but at higher temperatures they increase. The difference is explained by different initial populations of the levels.

Dielectronic recombination predominantly populates states with $l \lesssim 10$ (see, e.g., Appendix B.2). Collisions in this case mostly transfer recombined electrons to higher l s, increasing the probability of $\Delta n = 1$ transitions and, therefore, α -line emissivities.

Radiative recombination, especially at low temperatures, populates high- l states much more efficiently. In this case, populations of low- l levels relatively increase as a result of the l -changing collisions, and recombination line emissivities somewhat decrease.

In Fig. 14 we show the O V recombination line emissivities relative to their low-density values as a function of electron density at temperature $30\,000 \text{ K}$. Lines arising in transitions between higher levels increase relatively more, but in absolute terms the increase in emissivity is approximately constant, determined by the l -redistribution in the high- n levels.

5.3. Recombination lines of other elements

Our previous analysis mainly examined the oxygen recombination line emission, as the SD95 model allows us to make quantitative predictions about their fluxes and line ratios to the observed collisionally-excited lines. For other elements, no model results for ionic abundance distribution are available. Thus to predict their line fluxes it is necessary to solve a separate

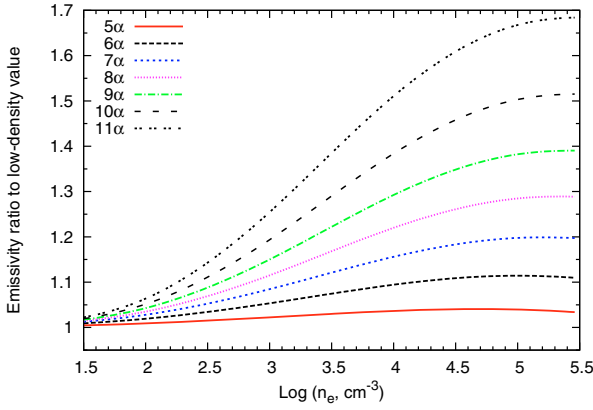


Fig. 14. Increase of O V α -line emissivities with electron density at temperature $T_e = 3 \times 10^4$ K.

problem of non-equilibrium plasma cooling and recombination after the shock front for dense clouds of different compositions. Such an analysis is outside the scope of this paper.

Nevertheless, it seems valuable to provide data on the recombination line emissivities as functions of temperature for the most typical elements. Then, from measured line ratios, it will be possible to reconstruct characteristic conditions in the emitting regions. As the two most typical examples of elements composing FMKs in Cas A, we concentrate on the recombination lines of silicon and sulphur. Approximate wavelengths of their recombination lines are given in Table 2 above.

Figure 15 presents low-density l -summed emissivities of the brightest optical and near-infrared recombination lines of silicon and sulphur ions expected to exist in the fast-moving knots. Note that Si IV and S VI lines are much weaker than of the other ions at $T_e > 10^4$ K due to the weakness of dielectronic recombination channels at these temperatures. Note also that the line emissivities in Si II and Si III ions start to increase sharply at about 12 000 K.

Thus these ions are the most sensitive tracers of plasma at temperatures between 15 000 and 30 000 K, when emissivities of O and S ions are still relatively weak. This is also seen in Figs. 8b,c, where the emissivities of the lines of Si III are a factor of 20–50 higher than that of O III and S III in the same conditions.

Similar to the case of oxygen recombination lines, the density dependences are not pronounced.

5.4. Recombination line flux ratios to collisionally-excited lines

The comparison of metal recombination line fluxes with the “traditional” collisionally-excited lines may also be a useful tool for plasma diagnostics.

As these two types of lines have different origins, their emissivity dependences on temperature and density are rather different. For example, collisionally-excited line emissivities exponentially decrease at temperatures below about $h\nu/k_B$, as thermal electron energies are not sufficient to excite the ion electronic transition. In contrast, recombination line emissivities at low temperatures increase with decreasing temperature.

Another useful property is that, even in the case when the recombination lines are not detected at all, from the limits of the ratios to the collisional lines it is possible to place constraints on the plasma parameters.

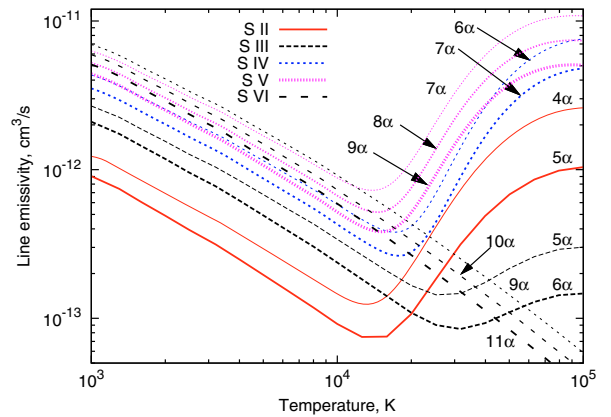
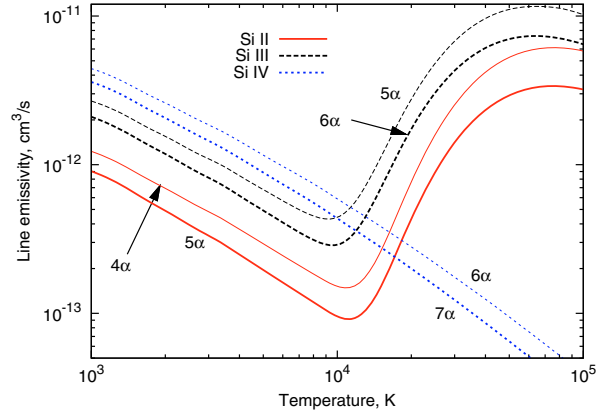


Fig. 15. Low-density l -summed emissivities of several optical and near-infrared silicon and sulphur recombination lines. Different colors represent different ions, plotted line thickness increases with spectral line wavelength.

In Fig. 16 we give ratios to several brightest collisionally-excited optical lines. The exponential increase of the ratios at low temperatures is clearly seen. Collisional line emissivities have been computed using the CHIANTI atomic database (Dere et al. 1997; Landi et al. 2006)

Recombination line flux ratios to the fine-structure far-infrared line emissivities are given in Fig. 17. As the CHIANTI database does not allow one to compute line emissivities down to 100 K, we computed them by extrapolating fine-structure transition electronic excitation collision strengths to low temperatures by a constant that should be reliable to within a factor of two. The collision strength values were adopted from calculations by Lennon & Burke (1994); Blum & Pradhan (1992); Tayal & Gupta (1999); Tayal (2000, 2006).

We note that observations of the far-infrared lines in the spectral range from 10 to 100 μm are impossible from the ground. But even from space, observations of these very intense lines cannot be performed with an angular resolution sufficient to resolve individual knots. They can result only in a signal integrated over many individual emitting objects.

The density dependences of recombination and collisionally-excited lines are also different. Forbidden line emissivity starts decreasing as $1/n_e$ at some critical density, whereas the recombination line emissivities may both decrease and increase depending on the plasma temperature (see above).

The best density indicators for relatively low temperatures and densities in the fast-moving knots are obviously ratios of different optical and near-infrared lines to the far-infrared lines that have critical densities of the order of $100\text{--}10^4 \text{ cm}^{-3}$. In an

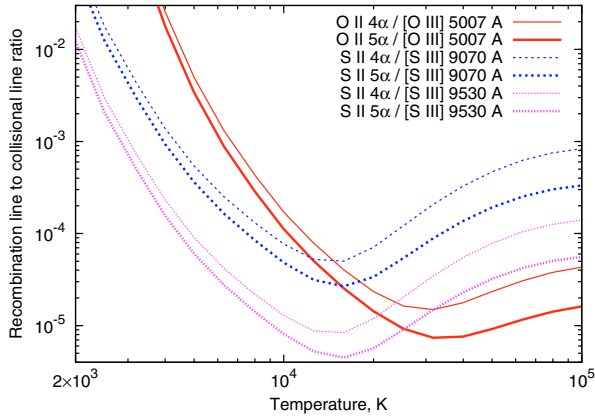


Fig. 16. Low-density emissivity ratios of recombination lines to several brightest optical collisionally-excited lines.

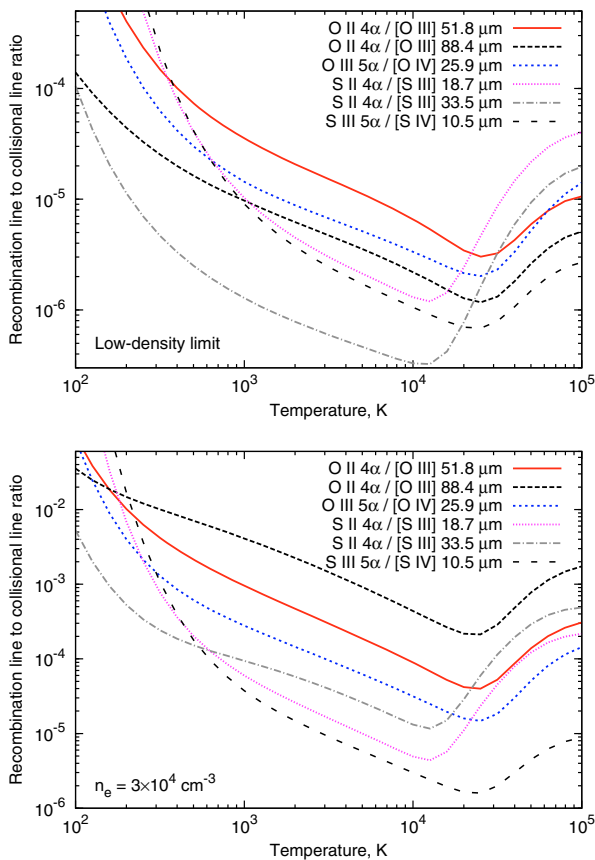


Fig. 17. Emissivity ratios of recombination lines to several far-infrared collisionally-excited lines. *Upper and lower panels* show emissivity ratios in the low-density limit applicable for the cold photoionized region (except for the 88.4 μm line) and the case of $n_e = 3 \times 10^4 \text{ cm}^{-3}$ typical for the cooling region after the shock front.

accompanying paper (Docenko & Sunyaev, to be submitted), we present such an analysis based on existing experimental data and compare the results to our predictions based on the SD95 model.

6. Conclusions

We have developed in detail a new method of rapidly recombining plasma diagnostics based on measurements of optical and near-infrared recombination lines of multiply-ionized metal atoms.

As an example, we have applied our method to the SD95 theoretical model of fast-moving knots in the Cassiopeia A supernova remnant and computed expected oxygen line fluxes from a single FMK of average size and the resulting recombination line ratios. Both the cold photoionized region before the shock front and the rapidly cooling region immediately after the shock front produce oxygen recombination lines strong enough to be observed with modern optical telescopes in the wavelength range between 0.5 and 3 μm .

At shorter wavelengths, two factors hamper the line observations: high absorption in the interstellar medium on the way from Cas A and the line splitting into widely separated multiple components with consequently lower intensities in each of them. The lines $n\alpha$ corresponding to transitions between $n \geq 6$ levels are the most promising, as they are not so strongly split and have 50–90% of the l -summed intensity in one or a few narrow components.

The precision of our RL flux estimates from Cas A is not expected to be better than a factor of several, as inconsistencies of similar magnitude are observed between the SD95 model predictions and far-infrared oxygen line observations (Docenko & Sunyaev, to be submitted).

Nevertheless, when detected, the recombination lines will allow us to determine the details of the photoionization and rapid cooling processes in the FMKs from the line intensities, intensity ratios to each other and to forbidden collisionally-excited lines and from the recombination line fine structure measurements. The measurements of the line structure demand higher signal-to-noise ratios that can nevertheless be achieved by modern telescopes in a reasonable integration time of a few hours.

One very interesting result is that the predicted O V and O VI recombination lines, being brightest in the cooling region recombination line spectra, arise in the temperature range significantly below 10^5 K , where there are essentially no O^{5+} and O^{6+} ions in collisional ionization equilibrium conditions.

It also would be very interesting to observe the recombination lines from the knots consisting mostly of silicon and iron. The existence of high-temperature shock-heated plasma having such a chemical composition has been proven by X-ray spectral observations (e.g., Hughes et al. 2000; Hwang et al. 2004), but detailed theoretical predictions of the cooling and ionization structure of such clouds have not yet been developed.

One of the purposes of this article is to attract attention to metal recombination lines radiated by plasma far out of the collisional ionization equilibrium and having highly-charged ions at low temperatures. Besides the supernova remnants, such plasma producing detectable metal recombination lines may exist in planetary nebulae, as well as near quasars and active galactic nuclei.

Acknowledgements. We are grateful to L. A. Vainshtein for valuable advices, providing results from the ATOM computer code and permission to use it. We also thank the anonymous referee for remarks making the paper easier to understand and for a useful reference on computation of hydrogenic radiative transition rates.

Appendix A: Determination of the upper cutoff n_{max}

Traditionally, the highly-excited level populations are characterized by the so-called departure coefficients b_{nl} , defined as the ratio of the actual level population N_{nl} to its thermodynamic equilibrium value N_{nl}^* . With n increasing, at levels $n > n_1$ the collisional l -redistribution processes establish an equilibrium population over l s, i.e., $b_n = b_{nl}$. The value of n_1 depends on the ion, as well as on the electron temperature and number density.

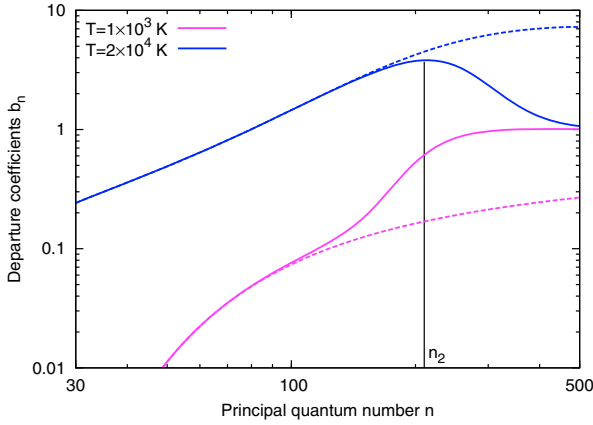


Fig. A.1. Departure coefficients b_n of recombining O^{5+} ions computed accounting for all processes (solid lines) and neglecting collisional n -redistribution, three-body recombination and collisional ionization (dashed lines) at electron temperatures $T_e = 1 \times 10^3$ K and 2×10^4 K and density $n_e = 5 \times 10^4$ cm^{-3} . At higher temperature dielectronic recombination dominates and significantly increases the level populations.

For higher ns , rates of collisional transitions involving changing n start rapidly increasing and from some $n > n_2$ determine the highly-excited level populations. Thus the b_n curve, itself defined only at $n > n_1$, has two distinct ranges as a function of n : below $n = n_2$ it is determined by recombination and radiative processes and above it rapidly tends to unity because of the processes relating different n level populations with each other and with the continuum: collisional n -redistribution, three-body recombination and collisional ionization. As an example, b_n s of Li-like ion O^{5+} at temperatures 1000 and 20 000 K and electron density 50 000 cm^{-3} are shown in Fig. A.1, assuming $b_n = b_{nl}$.

In this figure, we also show the departure coefficients, computed accounting only for radiative $n \rightarrow n'$ transitions. Such an approximation results in population computation errors at levels higher than about n_2 .

Let us now show that the electrons that recombined to levels $n > n_2$ are contributing relatively weakly to the total recombination and it is safe to introduce an upper cutoff n_{max} , neglecting the population of higher levels. Two cases – $b_{n_2} > 1$ and $b_{n_2} < 1$ – are discussed separately here.

In the case of $b_{n_2} > 1$, not introducing such a cutoff and neglecting $n \rightarrow n'$ collisions may result in a significant overestimation of the recombination rate – up to a factor of several. The easiest estimate of the cutoff position is the level where the total recombination rate into $n < n_{\text{max}}$ computed without accounting for collisional $n \rightarrow n'$ transitions equals the true total recombination rate. It is easy to understand that in this case $n_{\text{max}} \approx n_2$, as illustrated in the lower panel of Fig. A.2.

In the case of $b_{n_2} < 1$ the rates obtained neglecting collisional transitions between high levels will always underestimate the true recombination rates. However, for temperatures above about 10^3 K taking the upper cutoff value approximately equal to n_2 does not result in an error of more than about 20% for the relevant ions, as illustrated in the upper panel of Fig. A.2. Lower cutoff values will result in more significant underestimates of the total recombination rate and the line emissivities.

In the case of lower densities, when n_2 is very high, another natural limit $n_{\text{max}} \approx (100-200)$ arises from the general dependence of the DR rate on the principal quantum number, see, e.g., Sobelman et al. (1981).

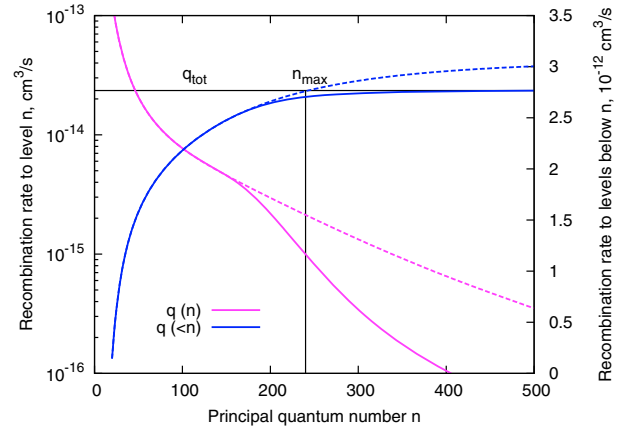
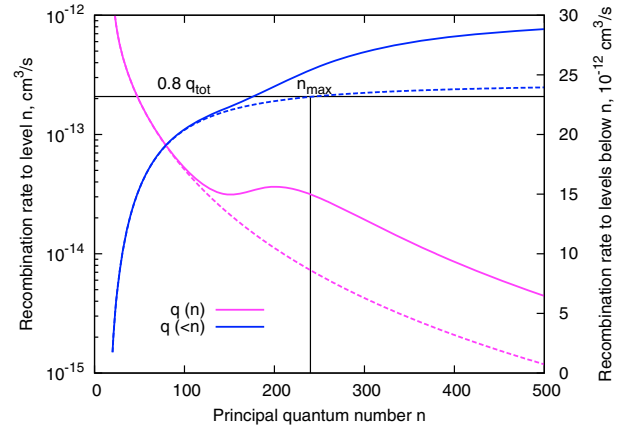


Fig. A.2. Recombination rates q of O^{5+} for $n_e = 5 \times 10^4$ cm^{-3} and $T_e = 1 \times 10^3$ K (upper panel) and 2×10^4 K (lower panel). The meaning of solid and dashed lines is as in Fig. A.1. The plot shows both rates for a given n (magenta curves) and cumulative rates for all levels below n (blue curves). The vertical line shows the upper cutoff n_{max} used for this ion in our calculations.

Appendix B: Atomic physics for level population computations

B.1. Radiative recombination

There are two major recombination processes populating high- n states in low-density plasmas: radiative and dielectronic recombination (RR and DR, respectively). In the radiative recombination process, a free electron directly recombines to a bound state (nl). A photon is simultaneously emitted, carrying away the released energy.

The radiative recombination level-specific cross sections σ_{RR} were computed from hydrogenic photoionization cross sections σ_{PI} by applying the detailed balance relation:

$$\sigma_{\text{RR}}(\mathcal{E} \rightarrow nl) = \frac{\alpha^2 Z^2}{2} \frac{2l+1}{n^2} \frac{v^2}{v_n(v-v_n)} \sigma_{\text{PI}}(nl \rightarrow \mathcal{E}), \quad (\text{B.1})$$

where \mathcal{E} is the electron energy prior to recombination, $h\nu_n = RyZ^2/n^2$ is the level binding energy, $h\nu = \mathcal{E} + h\nu_n$ is the energy of the emitted photon, Z is the recombining ion charge and α is the fine-structure constant. The photoionization cross sections σ_{PI} were calculated by the computer program of Storey & Hummer (1991).

The level-specific radiative recombination rates $q_{\text{RR}}(nl; T_e) \equiv \langle \sigma_{\text{RR}}(\mathcal{E} \rightarrow nl) \cdot \nu(\mathcal{E}) \rangle$ were then computed by numerical integration over the electron Maxwellian energy distribution for the temperature T_e (here ν denotes the electron velocity).

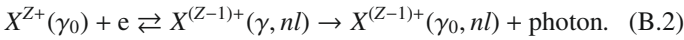
Using expressions from e.g. [Spitzer \(1956\)](#), it may be shown that the electron-electron collision timescale τ_{eec} is always shorter than the cooling time τ_{cool} at temperatures below 10^5 K where the line emission occurs, and electrons have enough time to reach the Maxwellian distribution. Roughly,

$$\tau_{\text{eec}} = 2.66 \text{ s} \frac{T_4^{3/2}}{n_{e,5} \ln \Lambda_C} \approx 0.16 \text{ s} \frac{T_4^{3/2}}{n_{e,5}},$$

where $T_e = 10^4 T_4$ K, $n_e = 10^5 n_{e,5} \text{ cm}^{-3}$ and $\Lambda_C \approx 3.92 \times 10^7 n_{e,5}^{-1/2} T_4^{3/2}$.

B.2. Dielectronic recombination

The DR is a two-step process (for reviews see, e.g., [Beigman et al. 1968](#); [Shore 1969](#); [Seaton & Storey 1976](#); [Sobelman et al. 1981](#)), illustrated in the simplest case by the following diagram:



The free electron e is first resonantly captured by the ion X^{Z+} (Z denotes the ion charge) with simultaneous core electron excitation from the ground state γ_0 to the state γ having excitation energy E_c . This process is called dielectronic capture. The resulting ion having two excited electrons is unstable with respect to autoionization – the inverse process of dielectronic capture.

The recombined ion then either autoionizes, or its excited core electron transits back to the ground state γ_0 and emits a resonant line photon, thus making the ion stable against autoionization.

Therefore the level-specific dielectronic recombination rate $q_{\text{DR}}(\gamma, nl; T_e)$ is a product of two factors: the dielectronic capture rate and the doubly-excited state stabilization probability. In the simple case described above it is expressed as

$$q_{\text{DR}}(\gamma, nl; T_e) = \left(\frac{2\pi\hbar^2}{mkT_e} \right)^{3/2} \frac{g_\gamma(2l+1)}{g_0} \frac{A_c A_a(\gamma, nl; \gamma_0)}{A_c + A_a(\gamma, nl; \gamma_0)} \exp\left(-\frac{\mathcal{E}}{kT_e}\right), \quad (\text{B.3})$$

where γ and γ_0 are the recombining ion ground and excited states, g_γ and g_0 are their statistical weights, $A_a(\gamma, nl; \gamma_0)$ is the doubly-excited state (γ, nl) autoionization rate with a core electron after the autoionization moving to the ground state γ_0 , A_c is the core state γ decay rate to the ground state γ_0 and \mathcal{E} is the electron energy prior to the recombination, $\mathcal{E} = E_c - \text{Ry} Z^2/n^2$.

We have determined the dielectronic recombination rates using two methods, which differ by the way they compute autoionization rates. In the first method, the autoionization rate is expressed in terms of the photoionization cross section using the dipole approximation for the inter-electronic interaction. A simple expression of this cross section and the autoionization rate in the $n \gg 1$ limit is then obtained using the quasi-classical (QC) approach ([Bureyeva & Lisitsa 2000](#)).

It is known that the dipole approximation is not applicable for this purpose for $l \leq 3$ states ([Beigman et al. 1981](#)). However, this is not a serious limitation when the dielectronic capture occurs via excitation of the recombining ion core electron without a change of its principal quantum number ($\Delta n_c = 0$). Such transitions are the most important ones in our case, as relevant plasma temperatures are much lower than the $\Delta n_c > 0$ transition excitation energies.

The second method is based on the use of the program ATOM ([Shevelko & Vainshtein 1993](#)). It computes autoionization rates by extrapolating below the threshold the electronic excitation cross section of the recombining ion core transition. This extrapolation method is based on the correspondence principle

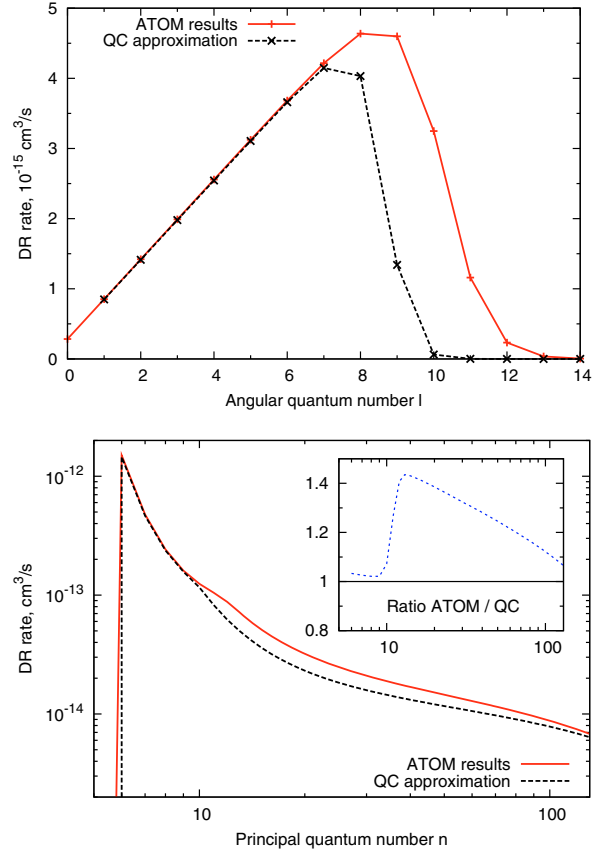


Fig. B.1. Comparison of l -resolved (*upper panel*) and l -summed (*lower panel*) O^{5+} ion dielectronic recombination rates computed by the two methods described in the text: the ATOM program and the quasiclassical (QC) approximation. The values are given for $T_e = 2 \times 10^4$ K, but the curves scale identically with temperature as long as $T_e \ll 10^6$ K, when $\Delta n_c > 0$ core excitations start playing a role. The l -resolved rates are given for $n = 20$.

and is thus precise in the limit of $n \gg 1$. Both in the QC approximation and the ATOM approach, the autoionization rates decrease as n^{-3} .

Comparison plots of the DR rates of O^{5+} forming O^{4+} with recombined electrons populating all n -levels and $n = 20$ level l -states are given in [Fig. B.1](#). It is seen that in the quasiclassical approximation, electrons populate lower l s, but higher n s. As can be inferred from [Eq. \(B.3\)](#), this corresponds to a sharper l -dependence of the autoionization rates. A comparison of scaled quasiclassical and quantum autoionization rates $A_a(2p, nl; 2s) \times n^3$ of the doubly-excited oxygen ion O^{4+} is shown in [Fig. B.2](#), indeed showing the inferred dependence.

It is clear from these data that the two models for the DR rates will result in significantly different line emissivities (see also [Fig. 1](#)). For our final results we use the ATOM rates, where available, as theoretical arguments ([Shevelko & Vainshtein 1993](#)) show that they are more precise than the quasiclassical ones.

For ions O^{5+} , O^{4+} , Si^{4+} , Si^{3+} , Si^{2+} , S^{6+} , S^{5+} and S^{4+} we used the ATOM rates. For other ions we implemented the quasiclassical expressions.

Comparison of the dielectronic recombination rates with other atomic process rates is shown in [Fig. B.3](#) for the case of the O^{4+} ion with highly-excited electrons on levels $n = 50$ and 200. It is seen that dielectronic recombination populates lower l s, but is more efficient at high- n levels. In the case of sufficiently

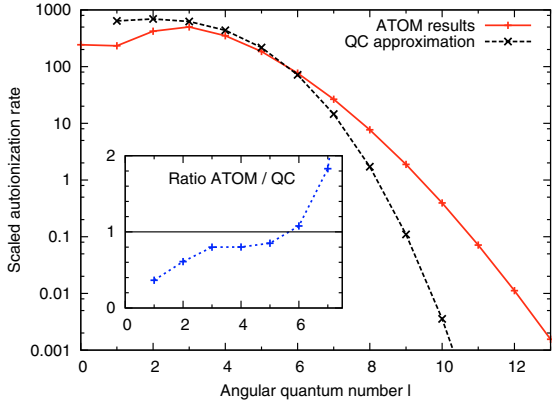


Fig. B.2. Comparison of scaled autoionization rates of O^{4+} ion in $(2p, nl)$ state autoionizing to O^{5+} ion in $2s$ state, $A_{\alpha}(2p, nl; 2s) \times n^3$, 10^{13} s^{-1} , in the quasiclassical approximation and computed by the program ATOM.

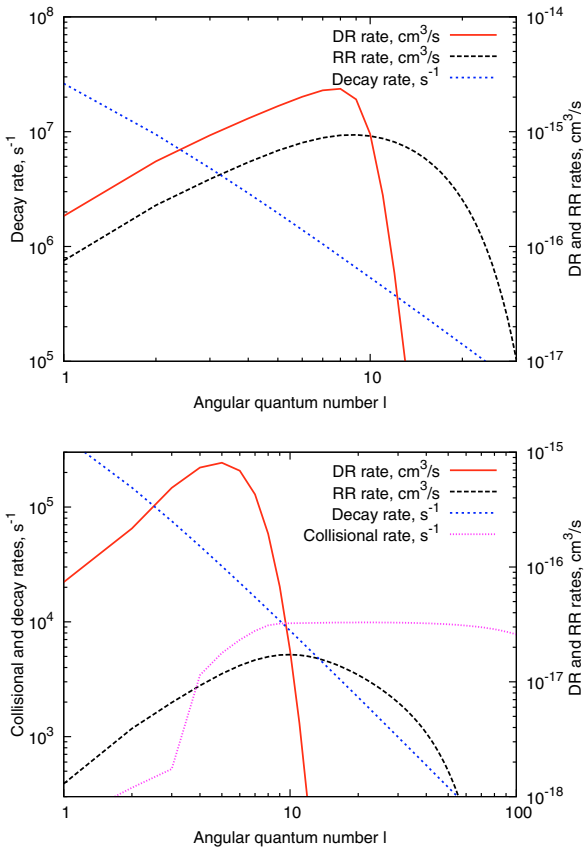


Fig. B.3. Elementary process rates for the O^{5+} ion recombining to form O^{4+} with highly-excited electrons having $n = 50$ (upper panel) and $n = 200$ (lower panel) at electron temperature $T_e = 2 \times 10^4 \text{ K}$. Collisional rates (total for transitions to all l') are shown for electron density $n_e = 5 \times 10^4 \text{ cm}^{-3}$ and are negligibly low for the $n = 50$ case.

high density the dielectronic recombination to low- l states is followed by rapid redistribution into much higher l s resulting in enhancement of the recombination line intensities.

B.3. Highly-excited level energies

In hydrogen atom the energies of (nl) levels are independent of l because of the shape of the Coulomb potential. In atoms with several electrons the changes in the potential energy curve

introduce variations of the highly-excited level energies $E(nl)$ with l . This dependence is usually parametrized by the expression

$$E(nl) = \text{Ry} \frac{z^2}{(n - \mu_{nl})^2},$$

where μ_{nl} denotes the quantum defect of the level (nl) and $z = Z + 1$ is the ion spectroscopic symbol. The quantum defects μ_{nl} rapidly decrease with increasing l and tend to a constant with increasing n (Seaton 1983).

Their values are important in this study for two reasons. Firstly, level energies $E(nl)$ and $E(n'l')$ determine transition energies $E(nl) - E(n'l')$ and, therefore, spectral line wavelengths. Transitions having the same values of n and n' have similar wavelengths. Small wavelength differences are in this case determined by the energy differences within n and n' groups of states – by the quantum defects of the levels.

Secondly, the collisional transition rates $C_{nl,n'l'}$ are dependent on the energy level splitting $|E(nl) - E(n'l')|$, growing as this splitting decreases. Therefore the quantum defects in this case determine rates of l -redistribution and recombination line flux dependence on electron density in plasma.

In the case of $l \leq 2$ the quantum defects for most ions are known and have been taken for our study from Ralchenko et al. (2007)⁵. In the next subsection we describe our method of computation of level energy shift from hydrogenic values $E_H(nl) = \text{Ry} z^2/n^2$ for $l > 2$ that can be expressed via quantum defects as

$$\Delta E(nl) \equiv E(nl) - E_H(nl) \approx 2\text{Ry} \frac{z^2}{n^3} \mu_l,$$

where we have assumed that $\mu_{nl} = \mu_l$, i.e. that the quantum defect does not depend on n and that it is small: $\mu_l \ll 1$.

The latter assumption is valid in our case of $l \gg 1$, when the (nl) states are “non-penetrating”, i.e., those in which the highly-excited electron wave function significantly differs from zero only outside the atomic core region. This property also allows us to use hydrogenic expressions for the description of such highly-excited states.

B.4. Computation of the level shifts for high- l states

Following the approach of Watson et al. (1980) and Dickinson (1981), we account for the non-penetrating (nl) state level shifts arising due to two effects: core polarizability and electrostatic quadrupole interaction with the core.

The energy shift induced by the core polarizability is proportional to the highly-excited electron radial integral $\langle r_{nl}^{-4} \rangle$ and, expressing it with the hydrogenic formula, gives (Seaton 1983)

$$\Delta E_p(nl) = \frac{\alpha_c z^4}{a_0^3 n^3} \frac{2(3 - l(l+1)/n^2)}{l(l+1)(2l-1)(2l+1)(2l+3)} \text{Ry}. \quad (\text{B.4})$$

Here a_0 is the Bohr radius and α_c is the core polarizability, taken for relevant ions from the handbook of Fraga et al. (1976) and the review by Lundeen (2005) and given for reference in Table B.1.

The electrostatic quadrupole interaction is absent for core states having total electronic angular momentum $J_c < 1$ or total orbital momentum $L_c < 1$. If $J_c \geq 1$, the highly-excited electron interacts with it, splitting the (nl) level into $2J_c + 1$ components numbered by the quantum number K , where $\mathbf{K} = \mathbf{J}_c + \mathbf{l}$.

⁵ URL: <http://physics.nist.gov/asd3>

Table B.1. Atomic parameters used for computations of the line substructure.

Ion	$\langle r_c^2 \rangle$	α_c	Ion	$\langle r_c^2 \rangle$	α_c	Ion	$\langle r_c^2 \rangle$	α_c
O II	1.20	1.35	Si II	4.33	11.7	S II	3.72	7.36
O III	0.97	0.94	Si III	3.79	7.42	S III	3.22	4.79
O IV	0.99	0.74	Si IV		0.20	S IV	2.44	3.24
O V	0.89	0.27				S V	2.24	1.28
O V		0.007				S VI		0.07

Note. Values are given in atomic units (a_0^2 for $\langle r_c^2 \rangle$ and a_0^3 for α_c). Column “ion” contains the ion spectroscopic symbol.

Normally, if the K -splitting is present, it is larger than the level shift due to core polarizability (Lundeen 2005).

The quadrupole shift in this case is given by the expression (Chang 1984):

$$\Delta E_q(nl, K) = (-1)^{l+L_c+S_c+K} (2J_c + 1) \begin{Bmatrix} J_c & J_c & 2 \\ L_c & L_c & S_c \end{Bmatrix} \times \begin{Bmatrix} J_c & J_c & 2 \\ l & l & K \end{Bmatrix} (l||C^{(2)}||l) (L_c||C^{(2)}||L_c) \langle r_c^2 \rangle \langle r_{nl}^{-3} \rangle 2Ry, \quad (\text{B.5})$$

where S_c is the total core spin momentum, $\{ : : \}$ denotes a $6j$ -symbol, $\langle r_c^2 \rangle$ and $\langle r_{nl}^{-3} \rangle$ are radial integrals in atomic units for core and highly-excited electrons, respectively, and $(l||C^{(2)}||l)$ are reduced matrix elements, given explicitly, e.g., by Sobelman (1979):

$$(l||C^{(2)}||l) = -\sqrt{\frac{l(l+1)(2l+1)}{(2l+3)(2l-1)}}.$$

The highly-excited electron radial integral can be determined using hydrogenic expression from, e.g., Bethe & Salpeter (1957). Core radial integrals $\langle r_c^2 \rangle$ were computed for all relevant ions using radial wave functions produced by the Flexible Atomic Code (FAC, Gu 2003). Where literature data for the $\langle r_c^2 \rangle$ were available (Sen 1979), the differences between them and the FAC values did not exceed about 10–15%. The values of $\langle r_c^2 \rangle$ used in our calculations are given in Table B.1.

Expression (B.5) may be approximated in the case of P core states ($L_c = 1$) and $l \gg 1$ by

$$\Delta E_{q,\max}(nl) \approx 0.2 \langle r_c^2 \rangle \langle r_{nl}^{-3} \rangle Ry = 0.2 \frac{z^3 \langle r_c^2 \rangle}{n^3 l(l+1)(l+1/2)} Ry, \quad (\text{B.6})$$

where in this case $\Delta E_{q,\max}(nl)$ gives the maximum shift of all the K -components. Components with both $\Delta E_{q,\max}(nl)$ and $-\Delta E_{q,\max}(nl)$ shifts are sometimes present.

Taking into account these effects, the total (nl) state shift to estimate the collisional l -redistribution rates was taken to be the maximum possible, i.e.,

$$\Delta E(nl) = \Delta E_{q,\max}(nl) + |\Delta E_p(nl)|.$$

As larger shifts correspond to smaller collisional cross sections, our approach may somewhat underestimate the l -redistribution rates.

We estimate that the resulting uncertainties of level splittings, in the case of the K -splitting present, correspond to the uncertainties in the electron density determination from the line ratios (see Sect. 5.2), being within a factor of about two.

B.5. Computation of the line substructure

As the ions of different elements have different values of α_c and $\langle r_c^2 \rangle$, the recombination line exact wavelengths will depend not only on the ion charge and the principal quantum numbers of the transition, but also on the element and the quantum numbers l , l' , K and K' .

From the above expressions determining energy level shifts it is possible to calculate the positions of all $nl \rightarrow n'l'$ line components $nlK \rightarrow n'l'K'$. Their relative fluxes are determined by the so-called line strengths S according to the expression (Chang 1984)

$$S(nlK, n'l'K') \propto (2K' + 1)(2K + 1) \begin{Bmatrix} K' & K & 1 \\ l & l' & J_c \end{Bmatrix}^2, \quad (\text{B.7})$$

if we assume that populations of the (nlK) -states are proportional to their statistical weights, i.e. $(2K + 1)$.

It was shown by Chang (1984) that electrons in the $l = 3$ levels in Si I still partially penetrate the core. Therefore also in our case the Si and S line substructure is described adequately only for $l > 3$. We give results also for $l = 3$, but the precision of line position predictions in this case is expected to be rather limited.

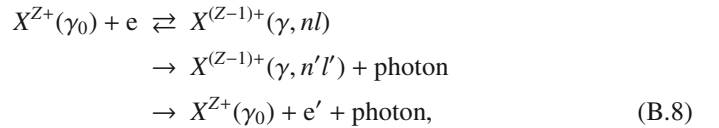
In the post-shock plasma of the fast moving knots, the density is high enough to establish a significant population of lowest excited fine-structure sublevels (Smeding & Pottasch 1979) that have typical excitation energies corresponding to temperatures of several hundred Kelvin.

In some cases such excited state populations strongly change the line substructure. For example, in the O^{3+} ion, the ground state $^2P_{1/2}$ has $J_c = 1/2$ and a quadrupole interaction with it is absent. However, the lowest excited state $^2P_{3/2}$ of this ion has $J_c = 3/2$. If the core electron is in the excited state prior to recombination, or arriving there after the DR process, the highly-excited levels will possess K -splitting and the resulting recombination lines will have a much richer substructure.

In our analysis we assume populations of the J_c sublevels proportional to their statistical weights.

B.6. Line emission without recombination

We also account for the following process, mostly not resulting in a recombination, but contributing, sometimes noticeably, to the spectral line emissivities:



i.e., highly-excited electron transitions instead of core transitions, followed by the captured electron autoionization. This process may be quite efficient for increasing $\Delta n = 1$ transition emissivities, as the radiative transition rates for the captured electron may be significantly higher than that of the core electron, if the core transition rate is low.

This is the case for $\Delta n_c = 0$ transitions, mostly contributing to the DR at relatively low temperatures. The rate of the described process (“dielectronic capture with line emission”, DCL) forming a line from the transition $(nl) \rightarrow (n'l')$ may be easily expressed via the rate of the dielectronic recombination as

$$q_{\text{DCL}}(\gamma, nl, n'l'; T_e) = q_{\text{DR}}(\gamma, nl; T_e) \frac{A_{nl, n'l'}}{A_c}. \quad (\text{B.9})$$

As the autoionization rates are much higher than the radiative transition rates within the ion, the probability of DCL is low and after the first captured electron transition it autoionizes, if it is energetically allowed.

To produce a noticeable effect, highly-excited electron transition rates should be at least comparable to the core transition rates, as DCL does not produce cascades. Therefore, only transitions between lower ns contribute significantly to the additional emission in lines. In the case of O^{5+} , the described process increases the DR contribution to the recombination line emissivity by roughly 5% for the 8α and 7α lines. From Eq. (B.9) it is clear that this fraction does not depend on temperature.

B.7. Estimates of the resulting uncertainties

Given the number of approximations made to achieve the final results – the metal recombination line emissivities and wavelengths – it might be useful to state explicitly the resulting uncertainties of these quantities.

The least reliable components for the calculation of the recombination line emissivities are dielectronic recombination rates and the upper cutoff position.

For the ions where the ATOM results are available, the low-density emissivity and flux uncertainties are expected to be about 10%. For the ions where the calculations are made using the quasi-classical expressions, the precision is lower and uncertainties may constitute up to 50%.

The choice of the upper cutoff n_{\max} position results in an additional emissivity uncertainty of less than 10% for the DR-dominated recombinations and an emissivity underestimate of less than 20% for the RR-dominated case.

The density dependences of the line emissivities are not strong and should be reliably modeled with any additional uncertainties being below 5–10%.

The absolute oxygen line fluxes are much less confidently predicted, as their values are based on the theoretical FMK model that shows differences when compared to the observed optical-to-infrared collisional line ratios up to a factor of several (Docenko & Sunyaev, to be submitted).

The line fine structure uncertainties come from the limited precision of the input atomic data (polarizabilities and radial integrals). It is estimated to be not worse than 10–20%, thus the line fine structure should be reliable.

The recombination line fine structure component relative intensities are the least reliably predicted as they depend on the recombining ion ground state populations. The results given above assume equilibrium populations; this may not be true at low densities or temperatures. Therefore the observed line structure may be significantly different from expected. However, the observed line structure will allow us to place additional constraints on the electron density and temperature from the fine structure component intensities.

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